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                CA/CAplus enhanced with legal status information for
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     5 AUG 24
                U.S. patents
NEWS
     6 SEP 09
                50 Millionth Unique Chemical Substance Recorded in
                CAS REGISTRY
NEWS 7 SEP 11
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                Taiwanese Content Expanded
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                Addition of SCAN format to selected STN databases
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        NOV 23 Annual Reload of IFI Databases
NEWS 12
        DEC 01 FRFULL Content and Search Enhancements
NEWS 13 DEC 01 DGENE, USGENE, and PCTGEN: new percent identity
                feature for sorting BLAST answer sets
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FILE COVERS 1907 - 1 Dec 2009 VOL 151 ISS 23 FILE LAST UPDATED: 30 Nov 2009 (20091130/ED) REVISED CLASS FIELDS (/NCL) LAST RELOADED: Aug 2009 USPTO MANUAL OF CLASSIFICATIONS THESAURUS ISSUE DATE: Aug 2009

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=> s jp58048048/pn

L1 1 JP58048048/PN

=> d all

L1 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2009 ACS on STN

AN 1983:430757 CAPLUS

DN 99:30757

OREF 99:4755a,4758a

ED Entered STN: 12 May 1984

TI Far UV-resist materials

PA Matsushita Electric Industrial Co., Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 3 pp.

CODEN: JKXXAF

DT Patent

```
LA
   Japanese
IC G03C001-72
ICA C08F002-48; H01L021-30
    74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
FAN.CNT 1
                   KIND DATE APPLICATION NO.
    PATENT NO.
    PΤ
<--
JP 63049211 B
PRAI JP 1981-147597
                            19881004
                             19810917
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
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JP 58048048 IC
                     G03C001-72
               ICA
                     C08F002-48; H01L021-30
               IPCI G03C0001-72 [ICM]; C08F0002-48 [ICA]; C08F0002-46
                      [ICA,C*]; H01L0021-30 [ICA]; H01L0021-02 [ICA,C*]
                IPCR G03F0007-20 [I,C*]; G03F0007-20 [I,A]; C08F0020-00
                      [I,C*]; C08F0020-00 [I,A]; C08F0020-32 [I,A];
                      G03F0007-039 [I,C*]; G03F0007-039 [I,A]; H01L0021-02
                      [I,C*]; H01L0021-027 [I,A]
                     G03F007/039
               ECLA
AΒ
    Copolymers of 70-50 mol% benzyl methacrylate (I) and 3-50 mol% glycidyl
    methacrylate (II) are used for photoresist material to expose with far
UV.
    The copolymers give highly sensitive and dry etchable pos.-working resist
    for microlithog. Thus, I 30, II 20, and azobisisobutylnitril 0.09 part
    were dissolved in benzene and heated 6 h at 90° to give a copolymer
    whose weight-average mol. weight was 290,000. A 10% solution of the
copolymer was
    spin-coated on a Si wafer and the surface of which was oxidized by baking
    to form a resist layer of 1 \mu\text{m} thickness. The wafer was prebaked at
    120^{\circ} for 30 min, exposed with far UV for 30 min and developed with
    Me iso-Bu ketone. The exposed resist was sputter-etched in CF4 gas of
0.1
    torr for 3 min at the power of 4.5 W/cm2. The reduced thickness of the
    resist layer after etching was 3200 Å, and the resist layer showed
    good resistance to dry etching.
ST photoresist UV sensitive pos working; benzyl methacrylate copolymer
    photoresist; glycidyl methacrylate copolymer photoresist
ΤТ
    Resists
       (photo-, pos.-working, UV-sensitive, benzyl methacrylate-glycidyl
       methacrylate copolymers as)
ΤТ
    86249-19-6
    RL: USES (Uses)
       (photoresist, UV-sensitive, pos.-working)
=> FIL REGISTRY
                                             SINCE FILE TOTAL ENTRY SESSION 6.62 6.84
COST IN U.S. DOLLARS
FULL ESTIMATED COST
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DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)

SINCE FILE
ENTRY
SESSION -0.82 -0.82

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STRUCTURE FILE UPDATES: 30 NOV 2009 HIGHEST RN 1194522-11-6 DICTIONARY FILE UPDATES: 30 NOV 2009 HIGHEST RN 1194522-11-6

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=> S 86249-19-6/RN

L2. 1 86249-19-6/RN

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=> D L2 SQIDE 1-

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- ANSWER 1 OF 1 REGISTRY COPYRIGHT 2009 ACS on STN L2
- 86249-19-6 REGISTRY RN
- 2-Propenoic acid, 2-methyl-, 2-oxiranylmethyl ester, polymer with CN phenylmethyl 2-methyl-2-propenoate (CA INDEX NAME) OTHER CA INDEX NAMES:
- 2-Propenoic acid, 2-methyl-, oxiranylmethyl ester, polymer with phenylmethyl 2-methyl-2-propenoate (9CI)
- 2-Propenoic acid, 2-methyl-, phenylmethyl ester, polymer with oxiranylmethyl 2-methyl-2-propenoate (9CI) OTHER NAMES:

CN Benzyl methacrylate-glycidyl methacrylate copolymer

MF (C11 H12 O2 . C7 H10 O3)x

CI PMS, COM

PCT Polyacrylic

LC STN Files: CA, CAPLUS, USPAT2, USPATFULL

DT.CA Caplus document type: Conference; Patent

RL.P Roles from patents: PREP (Preparation); PRP (Properties); RACT (Reactant or reagent); USES (Uses)

RLD.P Roles for non-specific derivatives from patents: PREP (Preparation); USES (Uses)

RL.NP Roles from non-patents: PRP (Properties); USES (Uses)

CM 1

CRN 2495-37-6 CMF C11 H12 O2

$$\begin{array}{c|c} ^{\rm H_2C} & {\rm O} \\ || & || \\ ^{\rm Me-} & {\rm C-C-O-CH_2-Ph} \end{array}$$

CM 2

CRN 106-91-2 CMF C7 H10 O3

PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT

16 REFERENCES IN FILE CA (1907 TO DATE)

5 REFERENCES TO NON-SPECIFIC DERIVATIVES IN FILE CA

16 REFERENCES IN FILE CAPLUS (1907 TO DATE)

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Page 5

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=> d his

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FILE 'REGISTRY' ENTERED AT 16:43:24 ON 01 DEC 2009
L2

1 S 86249-19-6/RN
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=> s 12

L3 16 L2

=> s 13 not 11

L4 15 L3 NOT L1

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CBIB ----- AN, plus Compressed Bibliographic Data
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PATS ----- PI, SO
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SIBIB ----- IBIB, no citations
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HITIND ----- IC, ICA, ICI, NCL, CC and index field (ST and IT)
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HITSTR ----- HIT RN, its text modification, its CA index name, and
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HITSEQ ----- HIT RN, its text modification, its CA index name, its
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FHITSTR ---- First HIT RN, its text modification, its CA index name, and
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FHITSEQ ---- First HIT RN, its text modification, its CA index name, its
             structure diagram, plus NTE and SEQ fields
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=> d all 1-15

- L4ANSWER 1 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
- 2009:1200918 CAPLUS ΑN
- DN 151:436915
- ED Entered STN: 02 Oct 2009
- ΤI Positive photosensitive resin composition and method of forming cured film
 - from the same
- Takita, Satoshi IN
- PΑ Fujifilm Corporation, Japan
- PCT Int. Appl., 64pp. CODEN: PIXXD2
- DT Patent
- LA Japanese
- CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 76

FAN.CNT 1

FAN.	AN.CNT I PATENT NO.				KIND DATE		APPLICATION NO.				DATE							
ΡI	PI WO 2009119878							WO 2009-JP56555				20090330						
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			CA,	CH,	CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DO,	DZ,	EC,	EE,	EG,	ES,
			FI,	GB,	GD,	GE,	GH,	GM,	GT,	HN,	HR,	HU,	ID,	IL,	IN,	IS,	KΕ,	KG,
								LA,								•		
								MY,										
			•	•	•	•		SD,	•	•	•	•	•	•	•	SY,	ТJ,	TM,
			,	,	,	,	,	UG,	,	,	,	,	,	,		~-		
		RW:	•	•	•			CZ,	•	•	•	•	•	•	•	•		
								LV,										
					•			CG,			•			•				
				•		•		KE,				•	SD,	SL,	54,	14,	UG,	ΔΜ,
	TD	2009						KZ,					9200	5		2	0090	330
		2009															0090	
PRAT		2008						2008			01 2	005	0200	O		4	0030	330
11/211		2008						2008										
CLAS		2000	000					2000	0020									
			PATENT FAMILY CLASSIFICATION CODES															
WO 2009119878 IPCI				G03F0007-039 [I,A]; C08F0020-28 [I,A]; C08F0020-42 [I,A]; C08F0020-00 [I,C*]; G03F0007-004 [I,A];														

WO 2009119878	IPCI	G03F0007-039 [I,A]; C08F0020-28 [I,A]; C08F0020-42
		[I,A]; C08F0020-00 [I,C*]; G03F0007-004 [I,A];
		G03F0007-40 [I,A]; H01L0021-027 [I,A]; H01L0021-02
		[I,C*]

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IPCR
                        G03F0007-039 [I,C]; G03F0007-039 [I,A]; C08F0020-00
                        [I,C]; C08F0020-28 [I,A]; C08F0020-42 [I,A];
                        G03F0007-004 [I,C]; G03F0007-004 [I,A]; G03F0007-40
                        [I,C]; G03F0007-40 [I,A]; H01L0021-02 [I,C];
                        H01L0021-027 [I,A]
JP 2009258722
                IPCI
                        G03F0007-039 [I,A]; G03F0007-004 [I,A]; G03F0007-075
                        [I,A]; G03F0007-40 [I,A]; H01L0021-027 [I,A];
                        H01L0021-02 [I,C*]; C08G0059-68 [I,A]; C08G0059-00
                        [I,C*]; C08F0020-26 [I,A]; C08F0020-00 [I,C*]
                 FTERM 2H025/AA01; 2H025/AA04; 2H025/AA10; 2H025/AA11;
                        2H025/AA14; 2H025/AB14; 2H025/AB16; 2H025/AB17;
                        2H025/AC01; 2H025/AD03; 2H025/BE00; 2H025/BF02;
                        2H025/BG00; 2H025/CB13; 2H025/CB14; 2H025/CB41;
                        2H025/CC04; 2H025/CC06; 2H025/CC17; 2H025/CC20;
                        2H025/FA17; 2H025/FA29; 2H025/FA30; 2H096/AA25;
                        2H096/AA27; 2H096/AA28; 2H096/BA11; 2H096/EA02;
                        2H096/GA09; 2H096/HA01; 2H096/HA03; 4J036/AD08;
                        4J036/AF06; 4J036/AF08; 4J036/AJ08; 4J036/AK08;
                        4J036/AK11; 4J036/DA10; 4J036/FB03; 4J036/GA26;
                        4J036/HA01; 4J036/JA09; 4J100/AL08P; 4J100/BA04P;
                        4J100/BA05P; 4J100/BA06P; 4J100/BB01P; 4J100/BC04P;
                        4J100/BC43P; 4J100/CA05; 4J100/DA01; 4J100/DA04;
                        4J100/JA38
JP 2009258723
                 IPCI
                        G03F0007-039 [I,A]; G03F0007-004 [I,A]; G03F0007-075
                        [I,A]; G03F0007-40 [I,A]; H01L0021-027 [I,A];
                        H01L0021-02 [I,C*]; C08F0220-26 [I,A]; C08F0220-00
                        [I,C*]
                 FTERM 2H025/AA01; 2H025/AA04; 2H025/AA10; 2H025/AA11;
                        2H025/AA14; 2H025/AB14; 2H025/AB16; 2H025/AB17;
                        2H025/AC01; 2H025/AD03; 2H025/BE00; 2H025/BF02;
                        2H025/BG00; 2H025/CC04; 2H025/CC06; 2H025/CC17;
                        2H025/CC20; 2H025/FA17; 2H025/FA29; 2H025/FA30;
                        2H096/AA25; 2H096/AA27; 2H096/AA28; 2H096/BA11;
                        2H096/EA02; 2H096/GA09; 2H096/HA01; 2H096/HA03;
                        4J100/AB07Q; 4J100/AL08P; 4J100/AL08Q; 4J100/AL08R;
                        4J100/AL09R; 4J100/AL10Q; 4J100/BA02P; 4J100/BA02Q;
                        4J100/BC04P; 4J100/BC43P; 4J100/BC43Q; 4J100/BC43R;
                        4J100/BC54Q; 4J100/CA03; 4J100/CA04; 4J100/CA05;
                        4J100/JA37
    MARPAT 151:436915
    The invention relates to a pos. photosensitive resin composition
AB
characterized
     by comprising: a resin which has a specific acrylic-acid-type structural
     unit generating a carboxy group upon dissociation of a dissociable
group, is
     alkali-insol. or sparingly alkali-soluble, and becomes alkali-soluble
     dissociation of the acid-dissociable group; a resin containing a
structural unit
     derived from an epoxidized radical-polymerizable monomer; a compound
having
     two or more epoxy groups per mol. (provided that the resin containing a
     structural unit derived from an epoxidized radical-polymerizable monomer
     is excluded); and a compound which generates an acid upon irradiation
with
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actinic rays having a wavelength of 300 nm or longer. Also provided is a
     method of forming a cured film such as smoothing layers, protective
     layers, interlayer-insulating layers, etc. from the composition
ST
    pos photosensitive resin cured film
ΤT
     Positive photoresists
        (permanent pos. photoresist; pos. photosensitive resin composition and
        method of forming cured film from the same)
     Photoimaging materials
ΤT
     Semiconductor device fabrication
        (pos. photosensitive resin composition and method of forming cured
film from
        the same)
ΙT
    Polymers
     RL: SPN (Synthetic preparation); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (pos. photosensitive resin composition and method of forming cured
film from
        the same)
     204993-57-7, CGI 725
ΙT
     RL: TEM (Technical or engineered material use); USES (Uses)
        (CGI 725; pos. photosensitive resin composition and method of forming
cured
        film from the same)
     852246-54-9, Irgacure PAG 108
ΙT
     RL: TEM (Technical or engineered material use); USES (Uses)
        (Irgacure PAG 108; pos. photosensitive resin composition and method of
        forming cured film from the same)
ΙT
     86249-19-6P, Glycidyl methacrylate-benzyl methacrylate copolymer
     155161-74-3P, Glycidyl methacrylate-benzyl methacrylate-methacrylic acid
                 293735-10-1P, (3,4-Epoxycyclohexyl)methyl methacrylate-benzyl
     copolymer
     methacrylate-methacrylic acid copolymer 1138028-34-8P, 1-Butoxyethyl
    methacrylate-benzyl methacrylate-methacrylic acid copolymer
     1138028-35-9P, Ethanol, 1-(benzyloxy)-, methacrylate-2-hydroxyethyl
    methacrylate copolymer
                             1138028-36-0P, 1-Ethoxyethyl methacrylate-benzyl
    methacrylate-2-hydroxyethyl methacrylate copolymer 1138028-37-1P,
     1-Ethoxyethyl methacrylate-benzyl methacrylate-methacrylic acid copolymer
     1138028-38-2P, 1-Cyclohexyloxyethyl methacrylate-p-methoxystyrene
                1138028-39-3P, Tetrahydropyranyl
    methacrylate-p-acetoxystyrene-2-hydroxyethyl methacrylate copolymer
     1138028-40-6P, Glycidyl acrylate-2-hydroxyethyl
     methacrylate-p-acetoxystyrene copolymer
                                              1138028-41-7P, Glycidyl
    p-vinylphenyl ether-1-ethoxyethyl methacrylate-p-acetoxystyrene copolymer
     1138028-42-8P, Glycidyl methacrylate-1-ethoxyethyl
     methacrylate-2-hydroxyethyl methacrylate copolymer
                                                          1138028-43-9P,
     Glycidyl methacrylate-1-ethoxyethyl methacrylate-2-hydroxyethyl
     methacrylate-benzyl methacrylate copolymer
     RL: SPN (Synthetic preparation); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (pos. photosensitive resin composition and method of forming cured
film from
        the same)
ΙT
     25068-38-6, JER 834
                          138361-24-7, Epikote 157S70
                                                         219651-50-0, CGI 1380
     852246-52-7, Irgacure PAG121
                                  955090-22-9, JER 1001
                                                           1042720-07-9,
     Irgacure PAG 103 1058132-49-2, JER 154
     RL: TEM (Technical or engineered material use); USES (Uses)
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(pos. photosensitive resin composition and method of forming cured
film from
       the same)
RE.CNT 14 THERE ARE 14 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE CITED REFERENCES
(1) E I Du Pont de Nemours & Co; JP 05-506731 A 1993
(2) E I Du Pont de Nemours & Co; WO 1991015808 A1 1993
(3) E I Du Pont de Nemours & Co; US 5120633 A 1993 CAPLUS
(4) E I Du Pont de Nemours & Co; EP 524250 A 1993 CAPLUS
(5) E I Du Pont de Nemours & Co; US 5262281 A 1993 CAPLUS
(6) Fujifilm Corp; WO 2008149947 A1 2008 CAPLUS
(7) Fujifilm Corp; WO 2009041619 A1 2009 CAPLUS
(8) JSR Corp; KR 1020040078554 A 2004
(9) JSR Corp; JP 2004264623 A 2004 CAPLUS
(10) JSR Corp; TW 266889 B 2004 CAPLUS
(11) Kyowa Hakko Chemical Co Ltd; JP 2006251296 A 2006 CAPLUS
(12) Shin-Etsu Chemical Co Ltd; KR 1020070119523 A 2007
(13) Shin-Etsu Chemical Co Ltd; US 20070292768 A1 2007 CAPLUS
(14) Shin-Etsu Chemical Co Ltd; JP 2007333933 A 2007 CAPLUS
    ANSWER 2 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
AN
    2009:751430 CAPLUS
    151:125286
DN
    Entered STN: 23 Jun 2009
ED
ΤI
    Alkali-soluble resins for photosensitive resin compositions with good
    adhesion, developability, and compatibility
    Heo, Yun Hui; Ahn, Jeong Ae; Kim, Han Su; Lim, Min Yeong; Yoo, Ji Heum;
ΤN
    Kim, Seon Hwa
    LG Chem, Ltd., S. Korea
PA
SO
    Repub. Korean Kongkae Taeho Kongbo, 16pp.
    CODEN: KRXXA7
DT
    Patent
LA
   Korean
CC
    38-3 (Plastics Fabrication and Uses)
    Section cross-reference(s): 74
FAN.CNT 1
    PATENT NO.
                      KIND DATE
                                        APPLICATION NO. DATE
                       ____
PI KR 2009061878
                       A
                            20090617 KR 2007-128867 20071212
PRAI KR 2007-128867
                              20071212
CLASS
PATENT NO.
              CLASS PATENT FAMILY CLASSIFICATION CODES
                      ______
                IPCI
                      C08F0220-00 [I,A]; C08F0220-10 [I,A]; C08F0210-00
                      [I,A]; G03F0007-027 [I,A]
                      C08F0220-00 [I,C]; C08F0220-00 [I,A]; C08F0210-00
                IPCR
                      [I,C]; C08F0210-00 [I,A]; C08F0220-10 [I,A];
```

G03F0007-027 [I,C]; G03F0007-027 [I,A]

GΙ

HO CH3
$$R^2$$
 CH3 OH CH_3 CHCH2CH2COOCH2CHYOCO-C=CH2 X^1

AB Title alkali-soluble resins comprises repeated units CH2:CAX1, CH2:CHX2OCOCH2CH(OCOZCO2H)YOCOCHX1:CH2, and I, wherein A = Ph, benzyloxycarbonyl, methyloxycarbonyl, ethyloxycarbonyl, isobutyloxycarbonyl, t-butyloxycarbonyl, cyclohexyloxycarbonyl, or isobornyloxycarbonyl; X1, X2 = H, C1-3 alkyl or alkoxy; Y = C1-3 alkylene,

ethylene oxide, or propylene oxide; Z = C1-3 alkylene, cyclohexenylene, cyclohexanylene or phenylene; and R1, R2 = H or OH.

ST alkali soluble resin photosensitive compn adhesion developability compatibility

IT Photoresists

(alkali-soluble resins for photosensitive resin compns. with good adhesion, developability, and compatibility)

IT 1169867-01-9P

RL: IMF (Industrial manufacture); POF (Polymer in formulation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses) (alkali-soluble resins for photosensitive resin compns. with good adhesion, developability, and compatibility)

IT 86249-19-6P, Benzyl methacrylate-glycidyl methacrylate copolymer 1169866-99-2P 1169867-00-8P

RL: IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation); RACT

(Reactant or reagent)

(alkali-soluble resins for photosensitive resin compns. with good adhesion, developability, and compatibility)

ΙT 80-62-6D, Methyl methacrylate, copolymers 85-43-8D, ester with hydroxy-containing polymers 85-44-9D, Phthalic anhydride, ester with hydroxy-containing polymers 96-33-3D, Methyl acrylate, copolymers 97-63-2D, Ethyl methacrylate, copolymers 97-86-9D, Isobutyl methacrylate, copolymers 97-90-5D, Ethylene glycol dimethacrylate, copolymers 100-42-5D, Styrene, copolymers 101-43-9D, Cyclohexyl methacrylate, copolymers 106-63-8D, Isobutyl acrylate, copolymers 108-30-5D, Succinic anhydride, ester with hydroxy-containing polymers 140-88-5D, Ethyl acrylate, copolymers 585-07-9D, tert-Butyl methacrylate, copolymers 1121-34-2D, Malic anhydride, ester with hydroxy-containing polymers 1663-39-4D, tert-Butyl acrylate, copolymers 2274-11-5D, Ethylene glycol diacrylate, copolymers 2495-35-4D, Benzyl 2495-37-6D, Benzyl methacrylate, copolymers acrylate, copolymers 3066-71-5D, Cyclohexyl acrylate, copolymers 3253-41-6D, Pentaerythritol tetramethacrylate, copolymers 3524-66-1D, Pentaerythritol 3524-68-3D, Pentaerythritol triacrylate, trimethacrylate, copolymers copolymers 4986-89-4D, Pentaerythritol tetraacrylate, copolymers 5888-33-5D, Isobornyl acrylate, copolymers 7534-94-3D, Isobornyl

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methacrylate, copolymers 25852-47-5D, Polyethylene glycol
     dimethacrylate, copolymers 26570-48-9D, Polyethylene glycol diacrylate,
     copolymers
     RL: TEM (Technical or engineered material use); USES (Uses)
        (alkali-soluble resins for photosensitive resin compns. with good
        adhesion, developability, and compatibility)
    ANSWER 3 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
    2009:385185 CAPLUS
ΑN
DN
    150:410239
ED
    Entered STN: 02 Apr 2009
    Positive-type photosensitive resin composition, and method for formation
TΤ
     of cured film using the same
     Takita, Satoshi
ΙN
    Fujifilm Corporation, Japan
PA
    PCT Int. Appl., 51pp.
SO
    CODEN: PIXXD2
DT
    Patent
LA
    Japanese
CC
     74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
     Section cross-reference(s): 38
FAN.CNT 1
                      KIND DATE
                                         APPLICATION NO.
    PATENT NO.
                       ----
                        A1 20090402 WO 2008-JP67496
PΙ
    WO 2009041619
                                                                 20080926
        W: AE, AG, AL, AM, AO, AT, AU, AZ, BA, BB, BG, BH, BR, BW, BY, BZ,
            CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DO, DZ, EC, EE, EG, ES,
            FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, KE, KG,
            KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LY, MA, MD, ME,
            MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL,
            PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, ST, SV, SY, TJ, TM,
            TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW
         RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU,
             IE, IS, IT, LT, LU, LV, MC, MT, NL, NO, PL, PT, RO, SE, SI, SK,
             TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD,
             TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW,
            AM, AZ, BY, KG, KZ, MD, RU, TJ, TM
JP 2009098673 A 20090507
PRAI JP 2007-256203 A 20070928
                                         JP 2008-246883 20080925
    JP 2008-246883
                        Α
                              20080925
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
 WO 2009041619 IPCI G03F0007-039 [I,A]; G03F0007-004 [I,A]; G03F0007-40
                       [I,A]; H01L0021-027 [I,A]; H01L0021-02 [I,C*]
                IPCR
                       G03F0007-039 [I,C]; G03F0007-039 [I,A]; G03F0007-004
                       [I,C]; G03F0007-004 [I,A]; G03F0007-40 [I,C];
                       G03F0007-40 [I,A]; H01L0021-02 [I,C]; H01L0021-027
                       [I,A]
 JP 2009098673
                IPCI
                       G03F0007-039 [I,A]; G03F0007-004 [I,A]; G03F0007-40
                       [I,A]; H01L0021-027 [I,A]; H01L0021-02 [I,C*];
                       H01L0051-50 [I,A]; H05B0033-10 [I,A]; H05B0033-22
                       [I,A]; G02F0001-1333 [I,A]; G02F0001-13 [I,C*];
                       C08F0020-28 [I,A]; C08F0020-00 [I,C*]; G03F0007-075
```

OS

AΒ

resin

having

ST

ΙT

of

TΤ

ΙT

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[I,A]
                 IPCR
                       G03F0007-039 [I,C]; G03F0007-039 [I,A]; C08F0020-00
                        [I,C]; C08F0020-28 [I,A]; G02F0001-13 [I,C];
                        G02F0001-1333 [I,A]; G03F0007-004 [I,C]; G03F0007-004
                        [I,A]; G03F0007-075 [I,C]; G03F0007-075 [I,A];
                        G03F0007-40 [I,C]; G03F0007-40 [I,A]; H01L0021-02
                        [I,C]; H01L0021-027 [I,A]; H01L0051-50 [I,C];
                        H01L0051-50 [I,A]; H05B0033-10 [I,C]; H05B0033-10
                        [I,A]; H05B0033-22 [I,C]; H05B0033-22 [I,A]
                 FTERM 2H025/AA01; 2H025/AA04; 2H025/AA10; 2H025/AA11;
                        2H025/AA14; 2H025/AB14; 2H025/AB16; 2H025/AC01;
                        2H025/AD03; 2H025/BE00; 2H025/BF02; 2H025/BF15;
                        2H025/BG00; 2H025/CC04; 2H025/CC06; 2H025/CC20;
                        2H025/FA17; 2H025/FA29; 2H025/FA30; 2H090/HB11X;
                        2H090/HB13X; 2H090/HC11; 2H090/HC13; 2H090/HC15;
                        2H090/HD08; 2H096/AA25; 2H096/AA27; 2H096/AA28;
                        2H096/BA11; 2H096/EA02; 2H096/GA09; 2H096/HA01;
                        2H096/HA03; 3K107/AA01; 3K107/CC21; 3K107/CC45;
                        3K107/DD90; 3K107/DD97; 3K107/FF13; 3K107/GG06;
                        3K107/GG11; 4J100/AB07Q; 4J100/AJ02R; 4J100/AL08P;
                        4J100/AL08Q; 4J100/AL08R; 4J100/BA02P; 4J100/BA03Q;
                        4J100/BA03R; 4J100/BA04P; 4J100/BA05Q; 4J100/BA06P;
                        4J100/BA14Q; 4J100/BC04P; 4J100/BC43P; 4J100/BC43Q;
                        4J100/BC53P; 4J100/CA04; 4J100/CA05; 4J100/DA01;
                        4J100/DA04; 4J100/DA38; 4J100/JA38
    MARPAT 150:410239
    Disclosed is a pos.-type photosensitive resin composition comprising: a
    which has a specific acrylic acid-type constituent unit whose
dissociating
    group can be dissociated to produce a carboxyl group, which is insol. or
    poorly soluble in an alkali, and whose acid-dissociating group can be
dissociated to
    render the resin alkali-soluble; a resin which has a constituent unit
     a functional group capable of reacting with a carboxyl group to form a
     covalent bond; and a compound which can generate an acid upon being
     irradiated with an active ray or an radioactive ray. The pos.-type
    photosensitive resin composition is excellent in sensitivity, percentage
    residual film and storage stability. Also disclosed is a cured film
    produced by a cured film formation method using the pos.-type
    photosensitive resin composition  The cured film is excellent in heat
    resistance, an adhesion property, transmittance and the like.
    pos photosensitive resin compn cured film acid generator
    Dielectric films
     Photoimaging materials
     Semiconductor device fabrication
        (pos.-type photosensitive resin composition, and method for formation
        cured film using the same)
     Coating materials
        (protective layer; pos.-type photosensitive resin composition, and
        for formation of cured film using the same)
     204993-57-7 852246-52-7 852246-54-9
                                             852246-55-0
                                                             1138028-44-0
```

method

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RL: CAT (Catalyst use); USES (Uses)
       (acid generator in pos.-type photosensitive resin composition)
    86249-19-6P 155161-74-3P 293735-10-1P 1138028-34-8P
IT
    1138028-35-9P 1138028-36-0P 1138028-37-1P 1138028-38-2P
    1138028-39-3P 1138028-40-6P 1138028-41-7P 1138028-42-8P
    1138028-43-9P
    RL: POF (Polymer in formulation); SPN (Synthetic preparation); PREP
     (Preparation); USES (Uses)
       (resin in pos.-type photosensitive resin composition)
OSC.G
            THERE ARE 1 CAPLUS RECORDS THAT CITE THIS RECORD (1 CITINGS)
UPOS.G Date last citing reference entered STN: 09 Oct 2009
OS.G CAPLUS 2009:1200918
RE.CNT 17
            THERE ARE 17 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE CITED REFERENCES
(1) Ciba Specialty Chemicals Holding Inc; KR 1020060064700 A 2002
(2) Ciba Specialty Chemicals Holding Inc; WO 1999001429 A1 2002
(3) Ciba Specialty Chemicals Holding Inc; JP 2002508774 A 2002
(4) Ciba Specialty Chemicals Holding Inc; TW 550439 B 2002 CAPLUS
(5) Ciba Specialty Chemicals Holding Inc; US 6004724 A 2002 CAPLUS
(6) Ciba Specialty Chemicals Holding Inc; DE 69807489 D 2002
(7) Ciba Specialty Chemicals Holding Inc; DE 69807489 T 2002
(8) Ciba Specialty Chemicals Holding Inc; AU 8628198 A 2002
(9) Ciba Specialty Chemicals Holding Inc; EP 993445 A 2002 CAPLUS
(10) Kyowa Hakko Chemical Co Ltd; JP 2006251296 A 2006 CAPLUS
(11) NEC Corp; JP 2007186680 A 2007 CAPLUS
(12) Sumitomo Chemical Co Ltd; JP 2003195506 A 2003 CAPLUS
(13) Tokyo Ohka Kogyo Co Ltd; CN 101065709 A 2006 CAPLUS
(14) Tokyo Ohka Kogyo Co Ltd; KR 1020070072607 A 2006
(15) Tokyo Ohka Kogyo Co Ltd; EP 1817634 A 2006 CAPLUS
(16) Tokyo Ohka Kogyo Co Ltd; WO 2006059747 A1 2006 CAPLUS
(17) Tokyo Ohka Kogyo Co Ltd; JP 2006154569 A 2006 CAPLUS
L4
   ANSWER 4 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
AN 2008:1259816 CAPLUS
DN
   149:534985
ED
   Entered STN: 20 Oct 2008
TI heat-curable film-forming resin compositions used for protection of color
    filter in liquid crystal displays
ΙN
   Zhanq, Xiaoyu
PA
   BYD Company Limited, Peop. Rep. China
   Faming Zhuanli Shenging Gongkai Shuomingshu, 17pp.
    CODEN: CNXXEV
DT
    Patent
LA
    Chinese
    37-6 (Plastics Manufacture and Processing)
    Section cross-reference(s): 74
FAN.CNT 1
                              DATE APPLICATION NO. DATE
    PATENT NO.
                      KIND
                              DATE
PI CN 101284891 A 20081015 CN 2007-10090505
PRAI CN 2007-10090505 20070409
                                                                20070409
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
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               IPCI C08F0220-32 [I,A]; C08F0220-00 [I,C*]; C08K0005-36
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[I,A]; C08K0005-00 [I,C*]; G02B0005-23 [I,A];
                        G02B0005-22 [I,C*]; G02F0001-1335 [N,A]; G02F0001-13
                        [N,C*]
                 IPCR
                        C08F0220-00 [I,C]; C08F0220-32 [I,A]; C08K0005-00
                        [I,C]; C08K0005-36 [I,A]; G02B0005-22 [I,C];
                        G02B0005-23 [I,A]; G02F0001-13 [I,C]; G02F0001-1335
                        [I,A]
     The compns., having high storage stability, comprise a unit A and a unit
AB
     at a mol. ratio of (1-8):1, wherein unit A is acrylate containing epoxy
group;
     unit B is one or more of benzyl (meth)acrylate, phenylethyl
     (meth)acrylate, and Ph (meth)acrylate; the weight average mol. weight of
the
     film-forming resin is 5000-100,000. Thus, dripping mixture of 80 parts
     glycidyl methacrylate and 20 parts benzyl methacrylate in AIBN 2.5,
     propylene glycol Me ether acetate 50 and ethylene glycol Bu ether acetate
     50 parts to a mixed solvents containing 20 parts propylene glycol Me
ether
     acetate and 20 parts ethylene glycol Bu ether acetate and polymerizing at
     80° gave a film-forming resin, which was added with a curing agent
     containing 6.5 parts trimellitic anhydride and 6.5 parts ST 1000 (epoxy
     resin), 12 parts \gamma-qlycidoxypropyltrimethoxysilane, 0.2 parts FC
     4430, 30 parts propylene glycol Me ether acetate and 30 parts ethylene
     glycol Bu ether acetate to give a title composition
ST
     methacrylate heat curable filmforming compn color filter protection
ΙT
    Crosslinking agents
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
     Epoxy resins, reactions
IT
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
     86249-19-6P, Benzyl methacrylate-qlycidyl methacrylate copolymer
     1075277-49-4P
                    1075277-50-7P
     RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP
     (Properties); TEM (Technical or engineered material use); PREP
     (Preparation); USES (Uses)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
ΤТ
     2530-83-8, \gamma-Glycidoxypropyltrimethoxysilane
                                                    620961-93-5, FC 4430
     RL: MOA (Modifier or additive use); USES (Uses)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
     112-07-2, Ethylene glycol butyl ether acetate
                                                     10471-14-4,
     1-Methoxy-1-ethoxyethane
                               84540-57-8, Propylene glycol methyl ether
     acetate
     RL: NUU (Other use, unclassified); USES (Uses)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
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106-90-1D, Glycidyl acrylate, polymer with Ph derivs. (meth)acrylates
ΙT
     106-91-2D, Glycidyl methacrylate, polymer with Ph derivs. (meth)acrylates
     2177-70-0D, Phenyl methacrylate, polymer with epoxy-bearing
     (meth)acrylates 2495-37-6D, Benzyl methacrylate, polymer with
     epoxy-bearing (meth)acrylates 3683-12-3D, Phenethyl methacrylate,
     polymer with epoxy-bearing (meth)acrylates 55750-22-6D, 3,4-Epoxybutyl
     methacrylate, polymer with Ph derivs. (meth)acrylates 62066-42-6D,
     polymer with Ph derivs. (meth)acrylates 69960-59-4D, polymer with Ph
     derivs. (meth)acrylates 83201-25-6D, 3,4-Epoxybutyl acrylate, polymer
     with Ph derivs. (meth)acrylates 212963-28-5D, polymer with Ph derivs.
     (meth)acrylates 1075277-51-8D, polymer with Ph derivs. (meth)acrylates
     RL: POF (Polymer in formulation); PRP (Properties); TEM (Technical or
     engineered material use); USES (Uses)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
     85-42-7, Hexahydrophthalic anhydride 85-44-9, Phthalic anhydride
     89-32-7, Pyromellitic anhydride 552-30-7, Trimellitic anhydride
     2426-02-0 26283-70-5 26590-20-5, Methyltetrahydrophthalic anhydride
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (preparation of heat-curable film-forming resin compns. used for
protection
        of color filter)
L4
     ANSWER 5 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
AN
    2006:1284428 CAPLUS
   146:52543
DN
ED
   Entered STN: 08 Dec 2006
TI Pigment-containing heat-curable composition, color filter,
image-recording
     material, and producing color filter
ΙN
    Yamada, Toru
PA Fuji Photo Film Co., Ltd., Japan
SO U.S. Pat. Appl. Publ., 28pp.
     CODEN: USXXCO
DT Patent
LA English
INCL 430007000; 430271100
     74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
     Section cross-reference(s): 37, 38
FAN.CNT 1
                  KIND DATE APPLICATION NO. DATE
     PATENT NO.
PI US 20060275676 A1 20061207 US 2006-446396 20060605 KR 2006126404 A 20061207 KR 2006-49930 20060602 JP 2007011324 A 20070118 JP 2006-155227 20060602 JP 2007023262 A 20070201 JP 2006-155228 20060602 PRAI JP 2005-164840 A 20050603 JP 2005-173750 A 20050614
CLASS
 PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
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US 20060275676 INCL 430007000; 430271100

IPCI G02B0005-20 [I,A]

IPCR

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NCL
                        430/007.000; 430/271.100
                 ECLA
                        G02B005/20; C08J003/20
                        C08L0063-00 [I,A]; C08J0003-02 [I,A]
 KR 2006126404
                 IPCI
                 ECLA
                        G02B005/20; C08J003/20
 JP 2007011324
                 IPCI
                        G02B0005-20 [I,A]; G03F0007-004 [I,A]; G03F0007-40
                        [I,A]; G03F0007-11 [I,A]; G02F0001-1335 [I,A];
                        G02F0001-13 [I,C*]
                 IPCR
                        G02B0005-20 [I,C]; G02B0005-20 [I,A]; G02F0001-13
                        [I,C]; G02F0001-1335 [I,A]; G03F0007-004 [I,C];
                        G03F0007-004 [I,A]; G03F0007-11 [I,C]; G03F0007-11
                        [I,A]; G03F0007-40 [I,C]; G03F0007-40 [I,A]
                       2H025/AA03; 2H025/AA14; 2H025/AA17; 2H025/AB13;
                 FTERM
                        2H025/AC01; 2H025/AD01; 2H025/BC13; 2H025/BC42;
                        2H025/CA00; 2H025/CC11; 2H025/DA31; 2H025/DA39;
                        2H025/FA17; 2H025/FA35; 2H025/FA41; 2H048/BA02;
                        2H048/BA11; 2H048/BA43; 2H048/BA45; 2H048/BA48;
                        2H048/BB02; 2H048/BB42; 2H048/BB46; 2H091/FA04Y;
                        2H091/FB03; 2H091/FC10; 2H091/FD04; 2H091/LA12;
                        2H091/LA30; 2H096/AA27; 2H096/AA30; 2H096/BA05;
                        2H096/CA06; 2H096/EA02; 2H096/GA08; 2H096/GA36;
                        2H096/HA07; 2H096/HA23; 2H096/JA04; 2H096/KA02
 JP 2007023262
                 IPCI
                        C08L0101-00 [I,A]; G03F0007-11 [I,A]; G03F0007-105
                        [I,A]; G03F0007-09 [I,C*]; G03F0007-40 [I,A];
                        G02B0005-20 [I,A]; C08K0003-00 [I,A]; C08K0005-00
[I,A]
                 IPCR
                        C08L0101-00 [I,C]; C08L0101-00 [I,A]; C08K0003-00
                        [I,C]; C08K0003-00 [I,A]; C08K0005-00 [I,C];
                        C08K0005-00 [I,A]; G02B0005-20 [I,C]; G02B0005-20
                        [I,A]; G03F0007-09 [I,C]; G03F0007-105 [I,A];
                        G03F0007-11 [I,C]; G03F0007-11 [I,A]; G03F0007-40
                        [I,C]; G03F0007-40 [I,A]
                 FTERM 2H025/AB13; 2H025/AC01; 2H025/DA31; 2H025/FA41;
                        2H048/BA02; 2H048/BA45; 2H048/BA47; 2H048/BB02;
                        2H048/BB42; 2H096/AA28; 2H096/CA05; 2H096/EA02;
                        2H096/HA23; 2H096/JA04; 4J002/BF051; 4J002/CC161;
                        4J002/CC181; 4J002/CC191; 4J002/CD021; 4J002/CD051;
                        4J002/CD061; 4J002/CF011; 4J002/CF211; 4J002/CK021;
                        4J002/CP031; 4J002/DE076; 4J002/DE086; 4J002/DE096;
                        4J002/DE116; 4J002/DE126; 4J002/DE136; 4J002/DE146;
                        4J002/EA057; 4J002/ED027; 4J002/EE037; 4J002/EH037;
                        4J002/EH157; 4J002/EL067; 4J002/FD096; 4J002/GP00;
                        4J002/HA01
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT
    The pigment-containing heat-curable composition including a pigment
AB
dispersion
     solution is obtained by dispersing a heat-curable resin, a solvent, and a
     pigment, where the concentration of the pigment 50-100% with respect to
the total
     solid contents.
     color filter dry etch film pigmented epoxy resin dispersion; photoimaging
```

RL: POF (Polymer in formulation); TEM (Technical or engineered material

material pigmented epoxy resin dispersion

Epoxy resins, uses

use); USES (Uses)

G02B0005-20 [I,C]; G02B0005-20 [I,A]

ΤТ

```
(binder; pigment-containing heat-curable composition for
manufacturing color filter)
    Negative photoresists
    Positive photoresists
        (laminate; pigment-containing heat-curable composition for
manufacturing color filter)
    Optical filters
    Photoimaging materials
    Pigments, nonbiological
        (pigment-containing heat-curable composition for manufacturing color
filter)
    65697-21-4, Benzyl methacrylate/methacrylic acid copolymer 149984-16-7,
    Epolead GT 401
    RL: POF (Polymer in formulation); TEM (Technical or engineered material
    use); USES (Uses)
       (binder; pigment-containing heat-curable composition for
manufacturing color filter)
    86249-19-6, Benzyl methacrylate-glycidyl methacrylate copolymer
     244772-00-7, EHPE-3150
     RL: TEM (Technical or engineered material use); USES (Uses)
       (binder; pigment-containing heat-curable composition for
manufacturing color filter)
    916515-96-3, Benzyl methacrylate-Methacrylic acid-methyl
    methacrylate-Pentaerythritol tetraacrylate copolymer
     RL: POF (Polymer in formulation); TEM (Technical or engineered material
    use); USES (Uses)
       (photoresist; pigment-containing heat-curable composition for
manufacturing color
       filter)
    893072-86-1, FHi 3950
TΤ
    RL: TEM (Technical or engineered material use); USES (Uses)
       (photoresist; pigment-containing heat-curable composition for
manufacturing color
       filter)
L4
    ANSWER 6 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
AN 2005:450794 CAPLUS
DN 142:490400
ED Entered STN: 27 May 2005
TI Bottom antireflective coatings
IN Yao, Huirong; Ding-Lee, Shuji; Wu, Hengpeng; Xiang, Zhong
PA Az Electronic Materials Usa Corp., USA
SO U.S. Pat. Appl. Publ., 19 pp.
    CODEN: USXXCO
DT Patent
   English
LA
    ICM G03C001-76
IC
INCL 430270100; X43-028.11
    74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
    Section cross-reference(s): 35, 38
FAN.CNT 1
                      KIND DATE
    PATENT NO.
                                      APPLICATION NO.
                                                           DATE
                              _____
                                          _____
                              20050526 US 2003-721883
PΙ
   US 20050112494
                       A1
                                                                 20031126
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US 7030201
                        B2 20060418
                        A2 20050609 WO 2004-IB4412 20041113
    WO 2005052016
    WO 2005052016
                        A3 20060323
            AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH,
            CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD,
            GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC,
            LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI,
            NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY,
            TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW
        RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM,
            AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK,
            EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO,
            SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR,
            NE, SN, TD, TG
                         A2 20060823 EP 2004-816624
    EP 1692094
        R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
            IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, PL, SK,
            HR, IS, YU
                    A
W
PRAI US 2003-721883
                               20031126
    WO 2004-IB4412
                               20041113
              CLASS PATENT FAMILY CLASSIFICATION CODES
PATENT NO.
US 20050112494 ICM
                       G03C001-76
                INCL
                       430270100; X43-028.11
                IPCI
                       C08F0126-06 [I,A]; C08F0126-00 [I,C*]; C08F0226-06
                       [I,A]; C08F0226-00 [I,C*]; C08F0122-40 [I,A];
                       C08F0122-00 [I,C*]; C08F0004-44 [I,A]; C08F0004-00
                       [I,C*]; C07C0321-00 [I,A]
                       C07C0231-00 [I,C*]; C07C0231-08 [I,A]; C07D0207-00
                IPCR
                       [I,C*]; C07D0207-404 [I,A]; C08F0008-00 [I,C*];
                       C08F0008-30 [I,A]; C08F0220-00 [I,C*]; C08F0220-36
                        [I,A]; C08F0220-58 [I,A]; C09D0133-14 [I,C*];
                       C09D0133-14 [I,A]; C09D0133-24 [I,C*]; C09D0133-24
                        [I,A]; G03F0007-09 [I,C*]; G03F0007-09 [I,A];
                       C08F0126-00 [I,C]; C08F0126-06 [I,A]; C07C0321-00
                        [I,C]; C07C0321-00 [I,A]; C08F0004-00 [I,C];
                       C08F0004-44 [I,A]; C08F0122-00 [I,C]; C08F0122-40
                        [I,A]; C08F0226-00 [I,C]; C08F0226-06 [I,A]
                       430/270.100; 430/281.100; 526/260.000; 525/123.000;
                NCL
                        525/326.700; 525/326.800; 525/327.100; 525/328.200;
                        526/262.000; 526/304.000; 540/525.000; 544/175.000;
                        546/142.000; 546/183.000; 546/237.000; 546/296.000;
                        548/479.000; 548/547.000; 564/158.000; 564/159.000;
                        564/162.000
                       C07D207/404; C08F008/30+20/32; G03F007/09A
                ECLA
                       C08F0220-32 [ICM, 7]; C08F0220-00 [ICM, 7, C*];
WO 2005052016
                IPCI
                       C08F0008-46 [ICS,7]; C09D0133-14 [ICS,7]; C08F0008-00
                        [ICS,7]; C08F0020-36 [ICS,7]; C07C0231-08 [ICS,7];
                       C07C0231-00 [ICS, 7, C*]; C07D0207-404 [ICS, 7];
                       C07D0207-00 [ICS,7,C*]; C08F0008-30 [ICS,7];
                       C08F0020-32 [ICS,7]; C08F0020-58 [ICS,7]; C08F0020-00
                       [ICS,7,C*]; C09D0133-24 [ICS,7]; G03F0007-09 [ICS,7]
                 IPCR
                       C07C0231-00 [I,C*]; C07D0207-00 [I,C*]; C08F0008-00
                        [I,C*]; C08F0220-00 [I,C*]; C09D0133-14 [I,C*];
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C09D0133-24 [I,C*]; G03F0007-09 [I,C*]; C07C0231-08
                        [I,A]; C07D0207-404 [I,A]; C08F0008-30 [I,A];
                        C08F0220-36 [I,A]; C08F0220-58 [I,A]; C09D0133-14
                        [I,A]; C09D0133-24 [I,A]; G03F0007-09 [I,A]
                 ECLA
                        C07D207/404; C08F008/30+20/32; G03F007/09A
EP 1692094
                 IPCI
                        C07C0231-08 [ICM, 7]; C07C0231-00 [ICM, 7, C*];
                        C08F0220-58 [ICS,7]; C07D0207-404 [ICS,7]; C07D0207-00
                        [ICS, 7, C*]; C09D0133-14 [ICS, 7]; C08F0008-30 [ICS, 7];
                        C08F0008-00 [ICS, 7, C*]; C09D0133-24 [ICS, 7];
                        C08F0220-36 [ICS,7]; C08F0220-00 [ICS,7,C*];
                        G03F0007-09 [ICS, 7]
                        C07D207/404; C08F008/30+20/32; G03F007/09A
                 ECLA
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT
    MARPAT 142:490400
OS
AΒ
     The present invention relates to bottom antireflective coating compns.
and
     polymers useful in making such compns.
ST
     bottom antireflective coating photoresist photolithog
ΙT
     Antireflective films
     Photolithography
     Photoresists
        (bottom antireflective coatings)
     25167-42-4DP, Glycidyl methacrylate-styrene copolymer, Succinimide adduct
ΙT
     86249-19-6DP, Benzyl methacrylate-Glycidyl methacrylate copolymer,
     Succinimide adduct
                         851883-55-1P
     RL: SPN (Synthetic preparation); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (bottom antireflective coatings containing)
ΙT
     79-06-1, Acrylamide, reactions 108-24-7, Acetic anhydride
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (preparation of polymer for bottom antireflective coatings)
     1432-45-7P
IT
     RL: RCT (Reactant); SPN (Synthetic preparation); PREP (Preparation); RACT
     (Reactant or reagent)
        (preparation of polymer for bottom antireflective coatings)
              THERE ARE 15 CITED REFERENCES AVAILABLE FOR THIS RECORD
    CITED REFERENCES
(1) Anon; EP 0922715 A2 1999 CAPLUS
(2) Anon; English language abstract of JP37009212
(3) Anon; International Search Report for PCT IB2004004412
(4) Anon; Notification of Transmittal of International Search Report and the
    Written Opinion of the International Searching Authority for
    PCT/IB2004/004412for PCT/IB2004/004412for PCT/IB2004/004412
(5) Anon; Written Opinion of the International Search Authority for PCT
    IB2004004412
(6) Arase; US 20020156148 A1 2002 CAPLUS
(7) Baumann; US 4079041 A 1978 CAPLUS
(8) Lele; US 6369249 B1 2002 CAPLUS
(9) Meador; US 5919599 A 1999 CAPLUS
(10) Meador; US 6156479 A 2000 CAPLUS
(11) Muller; US 4532332 A 1985 CAPLUS
(12) Okazaki; US 6730763 B1 2004 CAPLUS
(13) Puligadda; US 20030004283 A1 2003 CAPLUS
(14) Simms; US 5424364 A 1995 CAPLUS
(15) Zweifel; US 4247660 A 1981 CAPLUS
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ANSWER 7 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
L4
AN 2005:344412 CAPLUS
DN 142:393910
ED Entered STN: 21 Apr 2005
TI Thermosetting coating compositions with good transparency, heat,
chemical,
    and sputtering resistance, adhesion, and smoothness
    Fukumura, Takanori; Sato, Hiroyuki; Itami, Setsuo; Watanabe, Eiji
ΤN
PA
    Chisso Corp., Japan
SO
    Jpn. Kokai Tokkyo Koho, 18 pp.
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
    ICM C08G059-46
TC:
    ICS G02B005-20; G02F001-1335
    42-10 (Coatings, Inks, and Related Products)
    Section cross-reference(s): 74
FAN.CNT 1
                            DATE
    PATENT NO.
                      KIND
                                        APPLICATION NO.
                                         _____
                       ____
                     A 20050421
A 20030909
                                        JP 2004-261841
    JP 2005105264
                                                              20040909
PRAI JP 2003-317373
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
 _____
JP 2005105264 ICM C08G059-46
               ICS
                     G02B005-20; G02F001-1335
                IPCI C08G0059-46 [ICM, 7]; C08G0059-00 [ICM, 7, C*];
                      G02B0005-20 [ICS, 7]; G02F0001-1335 [ICS, 7];
G02F0001-13
                      [ICS, 7, C*]
                IPCR C08G0059-00 [I,C*]; C08G0059-46 [I,A]; G02B0005-20
                      [I,A]; G02B0005-20 [I,C*]; G02F0001-13 [I,C*];
                      G02F0001-1335 [I,A]
                FTERM 2H048/BA02; 2H048/BA55; 2H048/BA62; 2H048/BB02;
                      2H048/BB37; 2H048/BB42; 2H048/BB46; 2H091/FA02;
                      2H091/FB03; 2H091/GA01; 2H091/GA03; 2H091/GA07;
                      2H091/GA13; 2H091/LA04; 2H091/LA06; 2H091/LA12;
                      4J036/AD08; 4J036/AD11; 4J036/AG00; 4J036/AJ09;
                      4J036/AK11; 4J036/DB15; 4J036/DB17; 4J036/DB22;
                      4J036/FB14; 4J036/JA15
    Title compns. comprise (A) polyesteramide resins obtained from
    tetracarboxylic dianhydrides, diamines, and polyhydroxy compds. 100,
epoxy
    resins 20-400, epoxy curing agents 15-60 parts (based on 100 parts epoxy
    resin). Thus, 3,3'-diaminodiphenyl sulfone 9.93, 1,4-butanediol 14.42,
    and 3,3',4,4'-diphenyl ether tetracarboxylic anhydride 62.04 g were
    polymerized to give 30%-solid polyester-polyamide solution with
viscosity 36.5
    mPa-s and weight average mol. weight 7600, 100 g of which was mixed with
    methacrylate-glycidyl methacrylate copolymer 30, trimellitic anhydride 6,
    3-glycidoxypropyltrimethoxysilane 3, and Byk 344 (surfactant) 0.69 g,
    applied on a substrate, dried at 80° for 3 min, and heated at
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220° for 30 min to give a test piece with good transparency, heat, chemical, and sputtering resistance, adhesion, and smoothness.

ST thermosetting coating transparency heat chem sputtering resistance adhesion smoothness; diaminodiphenyl sulfone butanediol diphenyl ether tetracarboxylic anhydride copolymer prepn; polyesteramide methyl glycidyl methacrylate trimellitic anhydride copolymer compn

IT Epoxy resins, uses

RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP (Properties); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(acrylic, blend with polyester-polyamides; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance, adhesion, and smoothness)

IT Epoxy resins, uses

RL: POF (Polymer in formulation); TEM (Technical or engineered material use); USES (Uses)

(alicyclic, blend with polyester-polyamides; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance,

adhesion, and smoothness)

IT Polysiloxanes, uses

RL: POF (Polymer in formulation); TEM (Technical or engineered material use); USES (Uses)

(amino-containing, reaction products with polyester-polyamides; thermosetting resin compns. with good transparency, heat, chemical,

sputtering resistance, adhesion, and smoothness)

IT Epoxy resins, uses

and

RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP (Properties); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(anhydride-cured, blend with polyester-polyamides; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance,

adhesion, and smoothness)

IT Coating materials

(chemical— and heat—resistant; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance, adhesion, and smoothness)

IT Transparent materials

(coatings; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance, adhesion, and smoothness)

IT Polyesters, uses

RL: POF (Polymer in formulation); TEM (Technical or engineered material use); USES (Uses)

(polyamide-, blend with epoxy resins; thermosetting resin compns. with good transparency, heat, chemical, and sputtering resistance, adhesion,

and smoothness)

IT Polysulfones, uses

RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP (Properties); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(polyamide-polyester-, blend with acrylic epoxy resins; thermosetting resin compns. with good transparency, heat, chemical, and sputtering

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resistance, adhesion, and smoothness)
ΤТ
     Polyesters, uses
     RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP
     (Properties); TEM (Technical or engineered material use); PREP
     (Preparation); USES (Uses)
        (polyamide-polysulfone-, blend with acrylic epoxy resins;
thermosetting
        resin compns. with good transparency, heat, chemical, and sputtering
        resistance, adhesion, and smoothness)
ΙT
     Polyamides, uses
     RL: POF (Polymer in formulation); TEM (Technical or engineered material
     use); USES (Uses)
        (polyester-, blend with epoxy resins; thermosetting resin compns. with
        good transparency, heat, chemical, and sputtering resistance,
adhesion,
        and smoothness)
ΤТ
     Polyamides, uses
     RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP
     (Properties); TEM (Technical or engineered material use); PREP
     (Preparation); USES (Uses)
        (polyester-polysulfone-, blend with acrylic epoxy resins;
thermosetting
        resin compns. with good transparency, heat, chemical, and sputtering
        resistance, adhesion, and smoothness)
ΙT
    Alcohols, uses
     RL: POF (Polymer in formulation); TEM (Technical or engineered material
     use); USES (Uses)
        (primary, reaction products with polyester-polyamides; thermosetting
        resin compns. with good transparency, heat, chemical, and sputtering
        resistance, adhesion, and smoothness)
    Coating materials
ΙT
        (smooth-surfaced; thermosetting resin compns. with good transparency,
        heat, chemical, and sputtering resistance, adhesion, and smoothness)
ΤТ
     Electroluminescent devices
     Liquid crystal displays
     Optical filters
     Optical imaging sensors
        (thermosetting resin compns. with good transparency, heat, chemical,
and
        sputtering resistance, adhesion, and smoothness)
ΤТ
     Coating materials
        (thermosetting; thermosetting resin compns. with good transparency,
        heat, chemical, and sputtering resistance, adhesion, and smoothness)
ΤТ
     Coating materials
        (transparent; thermosetting resin compns. with good transparency,
heat,
        chemical, and sputtering resistance, adhesion, and smoothness)
IΤ
     100-51-6DP, Benzyl alcohol, reaction products with polyester-polyamides
     106209-33-0DP, SMA 1000, reaction products with polyester-polyamides
     849133-83-1DP, reaction products with styrene-maleic anhydride copolymers
     or benzyl alc.
                      849133-83-1P
                                     849928-55-8P
    RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP
     (Properties); TEM (Technical or engineered material use); PREP
     (Preparation); USES (Uses)
        (blend with acrylic epoxy resin; thermosetting resin compns. with good
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transparency, heat, chemical, and sputtering resistance, adhesion, and
        smoothness)
ΙT
     198699-40-0P 681435-08-5P 849928-56-9P
     RL: IMF (Industrial manufacture); POF (Polymer in formulation); PRP
     (Properties); TEM (Technical or engineered material use); PREP
     (Preparation); USES (Uses)
        (blend with polyester-polyamide; thermosetting resin compns. with good
        transparency, heat, chemical, and sputtering resistance, adhesion, and
        smoothness)
    25067-05-4, Polyglycidyl methacrylate 25167-42-4, Glycidyl
ΙT
    methacrylate-styrene copolymer 28472-86-8, Glycidyl
    methacrylate-2-hydroxyethyl methacrylate copolymer 86249-19-6,
    Benzyl methacrylate-glycidyl methacrylate copolymer
    RL: POF (Polymer in formulation); TEM (Technical or engineered material
     use); USES (Uses)
        (blend with polyester-polyamide; thermosetting resin compns. with good
        transparency, heat, chemical, and sputtering resistance, adhesion, and
        smoothness)
OSC.G
             THERE ARE 2 CAPLUS RECORDS THAT CITE THIS RECORD (2 CITINGS)
UPOS.G Date last citing reference entered STN: 01 May 2009
OS.G CAPLUS 2009:490511; 2009:490496
    ANSWER 8 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
L4
    2005:33669 CAPLUS
AN
DN
    142:115119
ED
   Entered STN: 14 Jan 2005
TI Manufacture of polymers for radically curable polymer compositions for
    pattern formation
IN
   Kamata, Hirotoshi; Ota, Keisuke; Kai, Kazushi
PA Showa Denko K. K., Japan
SO Jpn. Kokai Tokkyo Koho, 28 pp.
    CODEN: JKXXAF
DT Patent
LA Japanese
IC
    ICM C08F008-14
    ICS G03F007-038; C08F290-08
    37-6 (Plastics Manufacture and Processing)
    Section cross-reference(s): 74
FAN.CNT 1
    PATENT NO.
                       KIND DATE APPLICATION NO. DATE
PI JP 2005008858 A 20050113 JP 2004-104236 20040331 PRAI JP 2003-150798 A 20030528
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
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 JP 2005008858 ICM
                       C08F008-14
                      G03F007-038; C08F290-08
                ICS
                       C08F0008-14 [ICM, 7]; C08F0008-00 [ICM, 7, C*];
                IPCI
                       G03F0007-038 [ICS,7]; C08F0290-08 [ICS,7]; C08F0290-00
                       [ICS, 7, C*]
                 IPCR
                       C08F0008-00 [I,C*]; C08F0008-14 [I,A]; C08F0290-00
                       [N,C*]; C08F0290-08 [N,A]; G03F0007-038 [I,A];
                       G03F0007-038 [I,C*]
                FTERM 2H025/AB14; 2H025/AB15; 2H025/AB17; 2H025/AB20;
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2H025/AC01; 2H025/AD01; 2H025/BC32; 2H025/BC42;
2H025/BC51; 2H025/BC53; 2H025/BC81; 2H025/BJ10;
2H025/CA01; 2H025/CA18; 2H025/CA20; 2H025/CA27;
2H025/CA28; 2H025/FA03; 2H025/FA17; 4J100/AB02Q;
4J100/AB03Q; 4J100/AB07Q; 4J100/AE18P; 4J100/AG04Q;
4J100/AL030; 4J100/AL040; 4J100/AL08P; 4J100/AL080;
4J100/AL09Q; 4J100/AL10P; 4J100/AM02Q; 4J100/AM15Q;
4J100/AM17Q; 4J100/AM19Q; 4J100/AQ06Q; 4J100/AQ08Q;
4J100/BA02H; 4J100/BA03Q; 4J100/BA08H; 4J100/BA14Q;
4J100/BA15H; 4J100/BA31Q; 4J100/BB17Q; 4J100/BB18Q;
4J100/BC04Q; 4J100/BC08Q; 4J100/BC12Q; 4J100/BC43Q;
4J100/BC53Q; 4J100/BC54P; 4J100/BC79Q; 4J100/CA04;
4J100/CA31; 4J100/HA11; 4J100/HA61; 4J100/HA62;
4J100/HC27; 4J100/HC34; 4J100/JA38; 4J127/AA01;
4J127/AA02; 4J127/AA03; 4J127/BB041; 4J127/BB081;
4J127/BB191; 4J127/BB221; 4J127/BB251; 4J127/BB301;
4J127/BC031; 4J127/BD061; 4J127/BE11X; 4J127/BE111;
4J127/BE27X; 4J127/BE271; 4J127/BE31X; 4J127/BE311;
4J127/BE34Y; 4J127/BE341; 4J127/BE39X; 4J127/BE391;
4J127/BG05X; 4J127/BG051; 4J127/BG10Y; 4J127/BG101;
4J127/BG17Y; 4J127/BG171; 4J127/CB341; 4J127/FA17
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GΙ

$$\begin{array}{c|c} - \text{O}-\text{CH}_2-\text{CH}-\text{CH}_2-\text{O} \\ \text{OH} \\ \end{array} \begin{array}{c} \text{O} \\ \text{O} \end{array} \begin{array}{c} \text{O} \\ \text{R}^1-\text{O} \\ \text{n} \end{array} \begin{array}{c} \text{CH}_2-\text{CH}=\text{CH}_2 \\ \text{n} \end{array}$$

AB The polymers have I [R1 = (cyclo)alkylene, aralkylene, arylene; n = 0-20] and optionally OCH2CH0HCH2OCOCR2:C (R2 = H, Me) as side chains. Thus, addition reaction of glycidyl methacrylate-Me methacrylate copolymer with acrylic acid and monoallyloxyethyl fumarate in the presence of tetrabutylammonium bromide gave a curable polymer, which was mixed with trimethylolpropane triacrylate and Irgacure 907 (photopolymn. catalyst), applied on a glass plate, dried, irradiated with UV, and developed to give

a pattern with high sensitivity.

ST acrylic polymer pattern formation curable; glycidyl methacrylate methyl polymer acrylate monoallyloxyethyl fumarate; tetrabutylammonium bromide catalyst addn polymer ester; trimethylolpropane triacrylate polymer pattern photocurable

IT Addition reaction catalysts Photoimaging materials

(manufacture of polymers for radically curable polymer compns. for pattern $% \left(1\right) =\left(1\right) +\left(1\right)$

formation)

IT Halides
Phosphines
Phosphonium compounds

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Quaternary ammonium compounds, uses
     RL: CAT (Catalyst use); USES (Uses)
        (manufacture of polymers for radically curable polymer compns. for
pattern
        formation)
ΙT
    Amines, uses
     RL: CAT (Catalyst use); USES (Uses)
        (tertiary; manufacture of polymers for radically curable polymer
compns. for
       pattern formation)
     56-37-1, Benzyltriethylammonium chloride
                                                56-93-9,
    Benzyltrimethylammonium chloride 603-35-0, Triphenylphosphine, uses
     1100-88-5, Benzyltriphenylphosphonium chloride 1530-32-1,
     Ethyltriphenylphosphonium bromide 1643-19-2, Tetrabutylammonium bromide
     2751-90-8, Tetraphenylphosphonium bromide
     RL: CAT (Catalyst use); USES (Uses)
        (manufacture of polymers for radically curable polymer compns. for
pattern
        formation)
ΙT
     820212-15-5P
                    820212-16-6P
     RL: IMF (Industrial manufacture); PREP (Preparation)
        (manufacture of polymers for radically curable polymer compns. for
pattern
        formation)
     820212-04-2P
                   820212-05-3P
     RL: IMF (Industrial manufacture); POF (Polymer in formulation); RCT
     (Reactant); PREP (Preparation); RACT (Reactant or reagent); USES (Uses)
        (manufacture of polymers for radically curable polymer compns. for
pattern
        formation)
     26141-88-8P, Glycidyl methacrylate-methyl methacrylate copolymer
IT
     86249-19-6P, Benzyl methacrylate-glycidyl methacrylate copolymer
     391675-16-4P, Monoallyloxyethyl fumarate
     RL: IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation);
RACT
     (Reactant or reagent)
        (manufacture of polymers for radically curable polymer compns. for
pattern
        formation)
     108-31-6, Maleic anhydride, reactions
ΤТ
                                             111-45-5, Ethylene glycol
     monoallyl ether
    RL: RCT (Reactant); RACT (Reactant or reagent)
        (manufacture of polymers for radically curable polymer compns. for
pattern
       formation)
    ANSWER 9 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
     2004:1059427 CAPLUS
AN
    142:39564
DN
ED
     Entered STN: 10 Dec 2004
ΤI
    Curable polymer compounds for photosensitive compositions with good
     photosensitivity
    Kamata, Hirotoshi; Ohta, Keisuke; Kai, Kazufumi
ΙN
PA
     Showa Denko K.K., Japan
SO
    PCT Int. Appl., 58 pp.
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CODEN: PIXXD2
     Patent
DT
LA
     English
IC
     ICM C08L071-02
     ICS C08F020-00
CC
     38-3 (Plastics Fabrication and Uses)
     Section cross-reference(s): 35, 74
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     PATENT NO.
                        KIND DATE APPLICATION NO.
                        WO 2004106431 A2 20041209
WO 2004106431 A3 20050224
                                          WO 2004-JP7471
PΤ
                                                                   20040525
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             CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD,
             GE, GH, GM, HR, HU, ID, IL, IN, IS, KE, KG, KP, KR, KZ, LC, LK,
             LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO,
             NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ,
             TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW
         RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM,
             AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE,
             SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE,
             SN, TD, TG
                                           JP 2004-102587
     JP 2005008857
                                20050113
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    EP 1629046
                         A2 20060301
B1 20080514
                                           EP 2004-734763
                                                                     20040525
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                                                                    20040525
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     CN 100343335
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20070125 US 2005-557173
     AT 395382
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     US 20070021571 A1 20070125
US 7569327 B2 20090804
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    JP 2003-151215 A 20030528
US 2003-478344P P 20030616
WO 2004-JP7471 W 20040525
PRAI JP 2003-151215
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C08G059/14K2D; C08G059/14K2D2; C08G059/14S;
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                       2H025/AA04; 2H025/AA09; 2H025/AA10; 2H025/AB13;
                       2H025/AB15; 2H025/AC01; 2H025/AD01; 2H025/BC14;
                       2H025/BC19; 2H025/BC74; 2H025/BC81; 2H025/BC85;
                       2H025/BC86; 2H025/FA17; 4J100/AB02Q; 4J100/AB03Q;
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                       4J100/BA03Q; 4J100/BA08H; 4J100/BA14Q; 4J100/BA15H;
                       4J100/BA16H; 4J100/BA31Q; 4J100/BB17Q; 4J100/BB18Q;
                       4J100/BC04Q; 4J100/BC08Q; 4J100/BC12Q; 4J100/BC23H;
                       4J100/BC43Q; 4J100/BC53Q; 4J100/BC54P; 4J100/BC79Q;
                       4J100/CA04; 4J100/CA31; 4J100/HA11; 4J100/HA61;
                       4J100/HA62; 4J100/HC27; 4J100/HC28; 4J100/HC29;
                       4J100/HC30; 4J100/HC34; 4J100/JA38
                       C08L0071-00 [I,C]; C08L0071-02 [I,A]; C08F0020-00
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                       C08L0071-00 [I,C]; C08L0071-02 [I,A]; C08F0020-00
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CN 1795239
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AT 395382
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US 20070021571
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                       C08F0008-00 [I,A]; C08L0071-02 [I,A]; C08L0071-00
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                       [I,A]; C08G0065-00 [I,C*]; C08G0065-332 [I,A];
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                       [I,C]; G03F0007-038 [I,A]
                NCL
                       525/386.000; 430/285.100; 430/007.000; 430/018.000;
                       430/287.100; 430/311.000; 430/325.000; 522/100.000;
                       522/142.000; 525/286.000; 525/301.000
                ECLA
                       C08F008/14+220/32; C08F008/14+220/14;
                       C08F008/14+220/18; C08F008/46+220/18;
                       C08F008/46+220/14; C08F008/46+220/28; C08F283/06;
                       C08F283/10; C08F290/04; C08F290/06; C08F290/14;
                       C08G059/14K2D; C08G059/14K2D2; C08G059/14S;
                       C08G065/332D; G03F007/033; G03F007/038S
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

 ${\tt AB}$ This invention relates to novel polymer compds. having a side chain I, and

a process for preparing the same and radical polymerizable curable compns.

using the same, wherein R1 = independently ≥1 organic residue selected from alkylene, branched alkylene, cycloalkylene, aralkylene, and arylene; R2 = independently ≥1 organic residue selected from alkylene, branched alkylene, alkenylene, branched alkenylene, cycloalkylene, cycloalkenylene,

Ι

and arylene; and n = 0-20 integer. Thus, glycidyl methacrylate 88.0, Me methacrylate 62.0, 2-mercaptoethanol 0.93, and propylene glycol monomethyl

ether acetate 350.0 g were heated at 90°, a solution containing glycidyl methacrylate 88.0, Me methacrylate 62.0, 2-mercaptoethanol 0.93, propylene

glycol monomethyl ether acetate 350.0, and AIBN 6.3 g was added therein and polymerized for 3 h to give a copolymer with weight average mol. weight $14,000,\ 300$

g of which was mixed with monoallyloxyethyl fumarate obtained from maleic anhydride and ethylene glycol monoallyl ether 38.0, acrylic acid 13.7, tetrabutylammonium bromide 3.0, and methoxyquinone 0.15 g, heated at 90° for 15 h, 44.0 g tetrahydrophthalic anhydride was added therein and heated at 45° to give a copolymer having a double bond with acid value 90 and weight average mol. weight 55,000, 100 parts of which (30%-solids)

was mixed with Light Acrylate TMP-A trimethylolpropane triacrylate 15, Irgacure 907 2.5, and 4,4'-bis(N,N-diethylamino)benzophenone 0.5 parts, applied on a glass substrate, dried, irradiated, and developed to give a test piece with good photosensitivity.

- ST curable polymer compd photosensitive compn; branched alkyl contg acrylic polymer prepn
- IT Acrylic polymers, uses

RL: TEM (Technical or engineered material use); USES (Uses) (branched; preparation of curable polymer compds. for photosensitive compns.)

IT Photoimaging materials

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Photoresists
        (preparation of curable polymer compds. for photosensitive compns.)
ΙT
     26141-88-8P, Glycidyl methacrylate-methyl methacrylate copolymer
     86249-19-6P, Benzyl methacrylate-glycidyl methacrylate copolymer
     391675-16-4P
    RL: IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation);
RACT
     (Reactant or reagent)
        (intermediate in polymer acrylate preparation; preparation of curable
polymer
        compds. for photosensitive compns.)
     79-10-7DP, Acrylic acid, reaction products with epoxy-containing acrylic
    polymers, carboxy-containing allyl compds., and tetrahydrophthalic
anhydride,
     polymers with triacrylates 85-43-8DP, Tetrahydrophthalic anhydride,
     reaction products with epoxy-containing acrylic polymers, acrylic acid,
and
     carboxy-containing allyl compds., polymers with triacrylates
15625-89-5DP,
    Light Acrylate TMP-A, polymers with allyl-containing branched acrylic
polymers
     26141-88-8DP, Glycidyl methacrylate-methyl methacrylate copolymer,
    reaction products with acrylic acid, carboxy-containing allyl compds.,
and
     tetrahydrophthalic anhydride, polymers with triacrylates
     86249-19-6DP, Benzyl methacrylate-glycidyl methacrylate copolymer,
    reaction products with acrylic acid, carboxy-containing allyl compds.,
and
     tetrahydrophthalic anhydride, polymers with triacrylates 391675-16-4DP,
     reaction products with epoxy-containing acrylic polymers, acrylic acid,
and
     tetrahydrophthalic anhydride, polymers with triacrylates
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (preparation of curable polymer compds. for photosensitive compns.)
ΙT
     108-31-6, Maleic anhydride, reactions
                                             111-45-5, Ethylene glycol
     monoallyl ether
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (reactant in monomer preparation; preparation of curable polymer
compds. for
       photosensitive compns.)
RE.CNT 1
             THERE ARE 1 CITED REFERENCES AVAILABLE FOR THIS RECORD
    CITED REFERENCES
(1) Anon; WO 03010124 A1 CAPLUS
    ANSWER 10 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
L4
    2004:872885 CAPLUS
ΑN
    141:372751
DN
    Entered STN: 21 Oct 2004
ED
ΤI
    Composition for formation of underlayer film for lithography containing
     epoxy compound and carboxylic acid compound
    Kishioka, Takahiro
ΙN
    Nissan Chemical Industries, Ltd., Japan
PA
SO
    PCT Int. Appl., 43 pp.
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CODEN: PIXXD2

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DT
     Patent
LA
     Japanese
IC
     ICM G03F007-11
     ICS C08G059-40; H01L021-027
CC
     74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
     Section cross-reference(s): 76
FAN.CNT 1
     PATENT NO.
                        KIND DATE
                                            APPLICATION NO.
     WO 2004090640 A1 20041021 WO 2004-JP4764
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         W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH,
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             LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI,
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     CN 1768306
                                            CN 2009-10134350
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                         A 20091007
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                         A
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     CN 101560323
     US 20060234156
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                         A1 20061019
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                         G03F0007-11 [ICM, 7]; C08G0059-40 [ICS, 7]; C08G0059-00
                         [ICS, 7, C*]; H01L0021-027 [ICS, 7]; H01L0021-02
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                         C08G059/40; G03F007/09A; G03F007/11
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                         [ICS, 7, C*]; H01L0021-027 [ICS, 7]; H01L0021-02
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[I,C]; C08G0059-40 [I,A]; G03F0007-09 [I,C*];
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 US 20060234156
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                        G03C0001-00 [I,A]
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                        G03F0007-09 [I,A]; G03F0007-11 [I,C*]; G03F0007-11
                        [I,A]
                 NCL
                        430/270.100; 430/271.100; 430/311.000; 430/330.000
                 ECLA
                        C08G059/40; G03F007/09A; G03F007/11
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT
AB
   A composition for formation of underlayer film for lithog. that is used
in the
     lithog. process for producing semiconductor devices; and an underlayer
     film exhibiting a dry etching rate greater than in the use of
    photoresists. In particular, a composition for formation of underlayer
film.
     capable of forming an underlayer film without the need to use a
     crosslinking reaction catalyzed by a strong acid, which composition
comprises a
     component having epoxy group (polymeric compound or compound) and a
component
    having phenolic hydroxyl group, carboxyl group, protected carboxyl group
     or acid anhydride structure (polymeric compound or compound).
ST
     antireflection compn underlayer film photolithog photoresist epoxy
    carboxylic acid
ΙT
    Antireflective films
    Photolithography
    Photoresists
     Semiconductor device fabrication
        (composition for formation of underlayer film for lithog. containing
ероху
        compound and carboxylic acid compound)
TT
     25067-05-4P, Glycidyl methacrylate homopolymer 86249-19-6P,
    Benzyl methacrylate-glycidyl methacrylate copolymer
                                                           155161-74-3P,
Benzvl
    methacrylate-glycidyl methacrylate-methacrylic acid copolymer
     156623-56-2P, Benzyl methacrylate-glycidyl methacrylate-2-hydroxyethyl
    methacrylate copolymer
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     use); PREP (Preparation); USES (Uses)
        (composition for formation of underlayer film for lithog, containing
ероху
        compound and carboxylic acid compound)
     2451-62-9, Tris(2,3-epoxypropyl)isocyanurate
                                                   2904-41-8,
TΤ
                                       9003-01-4, Poly(acrylic acid)
     Tris(2-carboxyethyl)isocyanurate
     RL: TEM (Technical or engineered material use); USES (Uses)
        (composition for formation of underlayer film for lithog. containing
ероху
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compound and carboxylic acid compound)
              THERE ARE 1 CAPLUS RECORDS THAT CITE THIS RECORD (1 CITINGS)
        1
UPOS.G Date last citing reference entered STN: 16 Feb 2009
OS.G CAPLUS 2006:734505
              THERE ARE 34 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT 34
RE
    CITED REFERENCES
(1) Arch Specialty Chemicals Inc; EP 1169357 A 2002 CAPLUS
(2) Arch Specialty Chemicals Inc; JP 2002539282 A 2002
(3) Arch Specialty Chemicals Inc; US 6492092 B1 2002 CAPLUS
(4) Clariant International Ltd; EP 1131678 A 2002 CAPLUS
(5) Clariant International Ltd; CN 1330779 T 2002 CAPLUS
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(9) Fuji Photo Film Co Ltd; JP 10-333336 A 1998 CAPLUS
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(12) Hyundai Electronics Ind Co Ltd; US 20020009595 A1 2001
(13) Hyundai Electronics Ind Co Ltd; GB 2357512 A 2001 CAPLUS
(14) Hyundai Electronics Ind Co Ltd; FR 2802934 A 2001 CAPLUS
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(22) Kabushiki Kaisha Hainikkusu Semiconductor; DE 10133716 A1 2002 CAPLUS
(23) Kabushiki Kaisha Hainikkusu Semiconductor; DE 10133717 A1 2002 CAPLUS
(24) Kabushiki Kaisha Hainikkusu Semiconductor; CN 1331254 A 2002 CAPLUS
(25) Kabushiki Kaisha Hainikkusu Semiconductor; CN 1331256 A 2002 CAPLUS
(26) Kabushiki Kaisha Hainikkusu Semiconductor; US 20020093069 A1 2002
(27) Kabushiki Kaisha Hainikkusu Semiconductor; US 20020127789 A1 2002 CAPLUS
(28) Kabushiki Kaisha Hainikkusu Semiconductor; JP 2002105137 A 2002 CAPLUS
(29) Kabushiki Kaisha Hainikkusu Semiconductor; KR 20022907 A 2002
(30) Kabushiki Kaisha Hainikkusu Semiconductor; KR 20022909 A 2002
(31) Kabushiki Kaisha Hainikkusu Semiconductor; JP 200297231 A 2002
(32) Kabushiki Kaisha Hainikkusu Semiconductor; GB 2364315 A 2002 CAPLUS
(33) Kabushiki Kaisha Hainikkusu Semiconductor; GB 2364317 A 2002 CAPLUS
(34) Tokyo Ohka Kogyo Co Ltd; JP 06-35201 A 1994 CAPLUS
    ANSWER 11 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
T.4
    2004:178255 CAPLUS
ΑN
DN
    140:219431
     Entered STN: 04 Mar 2004
ED
TT
     Epoxy resin compositions, solutions, and their films for protective films
     of color filters of liquid-crystal displays
IN
     Murata, Yasutake; Sasaki, Takeaki; Fujishiro, Koichi
PA
    Nippon Steel Chemical Co., Ltd., Japan
SO
     Jpn. Kokai Tokkyo Koho, 12 pp.
     CODEN: JKXXAF
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    Patent
LA
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IC
     ICM G02B005-20
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ICS

C08G059-24

CC 42-9 (Coatings, Inks, and Related Products) Section cross-reference(s): 73, 74

FAN.CNT 1

	PATENT NO.		KIND	DATE	APPLICATION NO.	DATE	
	JP 200406993 JP 2002-227		Α	20040304 20020805	JP 2002-227755	20020805	
PATI	ENT NO.	CLASS	PATENT I	FAMILY CLASS	IFICATION CODES		
JP 2004069930		ICM ICS IPCI	G02B005- C08G059- G02B0005	-24 5-20 [ICM,7]	; C08G0059-24 [I	CS,7]; C08G0059-	00
		IPCR		9-00 [I,C*]; G02B0005-20	- '	A]; G02B0005-20	
		FTERM	4J036/AI 4J036/A	D04; 4J036/AI J13; 4J036/AI	342; 4J036/AA04; 312; 4J036/AE07; 311; 4J036/CA21; 323; 4J036/JA01	4J036/AJ09;	

AB Title compns. comprise (A) epoxy resins containing (a) epoxy-containing acrylic

copolymers with mol. weight 25,000-100,000 and epoxy equivalent 200-400 g/equiv

20-45, (b) fluorene-containing epoxy resins G[OAOCH2CH(OH)CH2]nOAOG (G = glycidyl; A = fluorene derivative; n = 0-20) 15-40, (c) alicyclic epoxy resins

having ≥ 2 epoxy groups 10-35, and (d) aliphatic epoxy resins 5-35%. Thus, a composition containing benzyl methacrylate-glycidyl methacrylate copolymer,

ESF 300 (fluorene-type epoxy resin), Celloxide 2021P (alicyclic epoxy resin), ZX 1542 (trimethylolpropane triglycidyl ether), trimellitic anhydride, and SK 1 (blocked carboxylic acid) showed good storage stability and gave a heat-resistant coating with good surface smoothness.

ST fluorene acrylic epoxy coating color filter; heat resistance epoxy coating

color filter; liq crystal display epoxy resin coating; storage stability
fluorene acrylic epoxy coating

IT Epoxy resins, uses

RL: IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(acrylic-, cardo; epoxy resin compns. for heat-resistant protective films of color filters of LCD) $\,$

IT Cardo polymers

RL: IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(acrylic-epoxy-; epoxy resin compns. for heat-resistant protective films of color filters of LCD)

IT Liquid crystal displays

Optical filters

(epoxy resin compns. for heat-resistant protective films of color filters of LCD) $\,$

IT Coating materials

(heat-resistant; epoxy resin compns. for heat-resistant protective films of color filters of LCD)

```
42765-17-3, Trimethylolpropane triglycidyl ether homopolymer
ΙT
     RL: POF (Polymer in formulation); RCT (Reactant); TEM (Technical or
     engineered material use); RACT (Reactant or reagent); USES (Uses)
        (ZX 1542; epoxy resin compns. for heat-resistant protective films of
        color filters of LCD)
ΙT
     666263-69-0P
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (epoxy resin compns. for heat-resistant protective films of color
        filters of LCD)
     25085-98-7, Celloxide 2021P 31256-79-8, ESF 300
ΙT
     Benzyl methacrylate-glycidyl methacrylate copolymer
     RL: POF (Polymer in formulation); RCT (Reactant); TEM (Technical or
     engineered material use); RACT (Reactant or reagent); USES (Uses)
        (epoxy resin compns. for heat-resistant protective films of color
        filters of LCD)
     552-30-7, Trimellitic anhydride 593-29-3, Nonsoul SK 1
ΤТ
     RL: RCT (Reactant); TEM (Technical or engineered material use); RACT
     (Reactant or reagent); USES (Uses)
        (epoxy resin compns. for heat-resistant protective films of color
        filters of LCD)
     ANSWER 12 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
L4
AN
    2000:855677 CAPLUS
DN
     134:23519
ED
   Entered STN: 07 Dec 2000
TΙ
     Thermosetting anti-reflective coatings
IN Meador, Jim D.; Nowak, Kelly A.; Xu, Gu
PA
     Brewer Science, Inc., USA
    U.S., 11 pp., Cont.-in-part of U.S. 5,919,599.
SO
     CODEN: USXXAM
DT
    Patent
LA English
IC
    ICM G03F007-004
INCL 430270100
     74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
     Section cross-reference(s): 35, 38, 73
FAN.CNT 3
     PATENT NO.
                         KIND DATE
                                              APPLICATION NO.
    US 6156479 A 20001205 US 1999-273881
US 5919599 A 19990706 US 1997-940169
CN 100362428 C 20080116 CN 1998-809390
TW 483917 B 20020421 TW 1998-87116151
TW 477796 B 20020301 TW 2000-89101156
WO 2000057247 A1 20000928 WO 2000-US7463
                                                                     19990322
РΤ
                                                                       19970930
                                                                       19980928
                                                                      19980929
                                                                       20000125
                                                                       20000321
         W: CA, CN, JP, KR, SG
         RW: AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL,
             PT, SE
PRAI US 1997-940169
                          A2 19970930
                          Α
     US 1999-273881
                                  19990322
```

PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES

CLASS

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G03F007-004
 US 6156479
                 ICM
                 INCL
                        430270100
                        G03F0007-004 [ICM, 7]
                 IPCI
                        G03F0007-11 [I,C*]; G03F0007-11 [I,A]; C08F0008-00
                 IPCR
                        [I,C*]; C08F0008-00 [I,A]; C08F0220-00 [I,C*];
                        C08F0220-32 [I,A]; C08F0283-00 [I,C*]; C08F0283-10
                        [I,A]; C09D0133-06 [I,C*]; C09D0133-06 [I,A];
                        G03F0007-09 [I,C*]; G03F0007-09 [I,A]
                 NCL
                        430/270.100; 430/271.100
                 ECLA
                        C08F008/00+20/00; C08F283/10; C09D133/06B+B4+C;
                        G03F007/09A
US 5919599
                 IPCI
                        G03C0001-492 [ICM, 6]; G03C0001-005 [ICM, 6, C*];
                        C08K0063-00 [ICS,6]; C08F0283-10 [ICS,6]; C08F0283-00
                        [ICS, 6, C*]
                 IPCR
                        G03F0007-11 [I,C*]; G03F0007-11 [I,A]; C08F0008-00
                        [I,C*]; C08F0008-00 [I,A]; C08F0220-00 [I,C*];
                        C08F0220-32 [I,A]; C08F0283-00 [I,C*]; C08F0283-10
                        [I,A]; C09D0133-06 [I,C*]; C09D0133-06 [I,A];
                        G03F0007-09 [I,C*]; G03F0007-09 [I,A]
                 NCL
                        430/271.100; 430/270.100; 430/512.000; 523/436.000;
                        525/523.000; 525/533.000
                 ECLA
                        C08F008/00+20/00; C08F283/10; C09D133/06B+B4+C;
                        G03F007/09A
 CN 100362428
                 IPCI
                        G03C0001-005 [I,C]; G03C0001-492 [I,A]; G03C0001-815
                        [I,C]; G03C0001-815 [I,A]
                 IPCR
                        G03C0001-005 [I,C]; G03C0001-492 [I,A]; G03F0007-11
                        [I,C*]; G03F0007-11 [I,A]; C08F0008-00 [I,C*];
                        C08F0008-00 [I,A]; C08F0220-00 [I,C*]; C08F0220-32
                        [I,A]; C08F0283-00 [I,C*]; C08F0283-10 [I,A];
                        C09D0133-06 [I,C*]; C09D0133-06 [I,A]; G03C0001-815
                        [I,C]; G03C0001-815 [I,A]; G03F0007-09 [I,C*];
                        G03F0007-09 [I,A]
                 ECLA
                        C08F008/00+20/00; C08F283/10; C09D133/06B+B4+C;
                        G03F007/09A
 TW 483917
                 IPCI
                        C08L0033-08 [ICM, 7]; C08L0033-00 [ICM, 7, C*]
                 IPCR
                        G03F0007-11 [I,C*]; G03F0007-11 [I,A]; C08F0008-00
                        [I,C*]; C08F0008-00 [I,A]; C08F0220-00 [I,C*];
                        C08F0220-32 [I,A]; C08F0283-00 [I,C*]; C08F0283-10
                        [I,A]; C09D0133-06 [I,C*]; C09D0133-06 [I,A];
                        G03F0007-09 [I,C*]; G03F0007-09 [I,A]
                 ECLA
                        C08F008/00+20/00; C08F283/10; C09D133/06B+B4+C;
                        G03F007/09A
 TW 477796
                 IPCI
                        C08F0283-10 [ICM, 7]; C08F0283-00 [ICM, 7, C*]
                        C08F0283-00 [I,C*]; C08F0283-10 [I,A]
                 IPCR
                        C08F283/10
                 ECLA
 WO 2000057247
                 IPCI
                        G03C0001-492 [ICM, 7]; G03C0001-005 [ICM, 7, C*];
                        C08K0063-00 [ICS,7]; C08F0283-10 [ICS,7]; C08F0283-00
                        [ICS, 7, C*]
                 IPCR
                        C08F0283-00 [I,C*]; C08F0283-10 [I,A]
                 ECLA
                        C08F283/10
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT
     Anti-reflective coating compns. having improved etch rate, inter alia,
AB
are
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prepared from certain acrylic polymers and copolymers, such as, glycidyl methacrylate reacted with non-polycyclic carboxylic acid dyes and

```
ST
     thermosetting antireflective coating photoresist acrylic polymer
ΙT
     Photoresists
        (dye-attached acrylic polymer thermosetting anti-reflective coatings
        for)
ΙT
    Antireflective films
        (thermosetting anti-reflective coatings from dye-attached acrylic
        polymers)
ΙT
     62-23-7DP, 4-Nitrobenzoic acid, reaction products with poly(glycidyl
    methacrylate) 65-85-0DP, Benzoic acid, reaction products with
    poly(glycidyl methacrylate), preparation 99-34-3DP, 3,5-Dinitrobenzoic
     acid, reaction products with poly(glycidyl methacrylate) 108-95-2DP,
     Phenol, reaction products with poly(glycidyl methacrylate), preparation
     140-10-3DP, trans-Cinnamic acid, reaction products with poly(glycidyl
     methacrylate) 527-72-0DP, 2-Thiophenecarboxylic acid, reaction products
     with poly(glycidyl methacrylate) 610-30-0DP, 2,4-Dinitrobenzoic acid,
     reaction products with poly(glycidyl methacrylate)
                                                         3724-65-0DP,
Crotonic
     acid, reaction products with poly(glycidyl methacrylate)
                                                                16533-71-4DP,
     3,5-Dinitro-p-toluic acid, reaction products with glycidyl
     methacrylate-2-hydroxy-3-phenoxypropla acrylate copolymer
                                                                 16533-71-4DP,
     3,5-Dinitro-p-toluic acid, reaction products with poly(glycidyl
                   25067-05-4DP, Poly(glycidyl methacrylate), reaction
    methacrvlate)
    products with benzoic acid
                                86249-19-6DP, Benzyl
    methacrylate-glycidyl methacrylate copolymer, reaction products with
     2,4-dinitrobenzoic acid 297748-18-6DP, Glycidyl
    methacrylate-2-hydroxy-3-phenoxypropyl acrylate copolymer, reaction
    products with 3,5-dinitro-p-toluic acid
    RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (thermosetting anti-reflective coatings from dye-attached acrylic
       polymers)
             THERE ARE 17 CAPLUS RECORDS THAT CITE THIS RECORD (19 CITINGS)
OSC.G
       17
UPOS.G Date last citing reference entered STN: 03 Jul 2009
      CAPLUS 2007:484898; 2006:982616; 2005:450794; 2004:1080605;
2004:312306;
              2004:252079; 2004:100632; 2003:1007488; 2003:532225;
2002:960608;
              2002:814036; 2002:730510; 2002:368926; 2002:309856; 2002:241110;
              2001:417272; 2000:806411
             THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT 4
    CITED REFERENCES
(1) Dexter; US 4544691 1985 CAPLUS
(2) Dichiara; US 5482817 1996 CAPLUS
(3) Flaim; US 5693691 1997 CAPLUS
(4) Knors; US 5731385 1998 CAPLUS
     ANSWER 13 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
L4
ΑN
     1999:606042 CAPLUS
DN
     132:195349
ED
     Entered STN: 24 Sep 1999
ΤI
    Molecular dynamics simulations of polymer-membrane/solvent interfaces
ΑU
     Schepers, Claudia; Hofmann, Dieter; Paul, Dieter
CS
     GKSS Research Center, Institute of Chemistry, Teltow, D - 14513, Germany
```

non-polycyclic phenolic dyes, all light absorbing at a wavelength of 193

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Scientific Computing in Chemical Engineering II: Computational Fluid
SO
     Dynamics, Reaction Engineering, and Molecular Properties (1999), 134-142.
     Editor(s): Keil, Frerich. Publisher: Springer, Berlin, Germany.
    CODEN: 68ELAF
DT
    Conference
LA
    English
CC
     38-2 (Plastics Fabrication and Uses)
     Latest results from mol. dynamics simulations on pervaporation in the
     interfacial region between polymer and feed are reported.
organic
    mixture containing 80 % n-heptane and 20 % poly(Me Ph siloxane) (PMPhS)
and
     selected poly(methacrylates) containing 6-membered rings, e.g., benzyl-,
     cyclohexylmethyl- (PcHMA), a-naphthylmethyl-, 9-anthrymethyl-, and
     2,4,6-tri-tert-Bu-benzyl esters of methacrylic acid were studied.
     solubility related enrichment factor of 2 for the benzene component was
observed
     for PMPhS, all studied methacrylates sorbed preferentially the major
     component n-heptane. Although there was a fast diffusion observed in the
     case of PMPhS the selectivity is low in comparison to the PcHMA
containing
     polymer membrane.
     mol dynamics simulation polymethacrylate membrane solvent interface
ST
ΙT
    Diffusion
    Membranes, nonbiological
    Molecular dynamics
    Pervaporation
        (mol. dynamics simulations of polymer-membrane/solvent interfaces)
ΤT
    Polymers, uses
     Polysiloxanes, uses
     RL: PRP (Properties); TEM (Technical or engineered material use); USES
     (Uses)
        (mol. dynamics simulations of polymer-membrane/solvent interfaces)
ΙT
     9005-12-3, Poly[oxy(methylphenylsilylene)] 29320-20-5
     51960-29-3, Poly(9-anthrylmethyl methacrylate)
     259794-99-5
                   259795-01-2
     RL: PRP (Properties); TEM (Technical or engineered material use); USES
     (Uses)
        (mol. dynamics simulations of polymer-membrane/solvent interfaces)
OSC.G
              THERE ARE 1 CAPLUS RECORDS THAT CITE THIS RECORD (1 CITINGS)
UPOS.G Date last citing reference entered STN: 16 Feb 2009
OS.G CAPLUS 2000:578873
RE.CNT 7
              THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS RECORD
    CITED REFERENCES
(1) Fritz, L; Polymer 1997, V38, P1035 CAPLUS
(2) Fritz, L; Polymer 1998, V39, P2531 CAPLUS
(3) Hofmann, D; J Membr Sci 1998, V144, P145 CAPLUS
(4) MSI; Discover Simulation Tools, Release 96.0 and 4.0.0, User Guide,
    www.msi.com/doc/ 1996
(5) Marrink, S; J Phys Chem 1996, V100, P16729 CAPLUS
(6) Mulder, M; Polymeric Gas Separation Membranes 1991
```

L4

(7) Theodorou, D; Macromolecules 1986, V10, P139

ANSWER 14 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN

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1997:515447 CAPLUS
AN
DN
   127:123091
OREF 127:23727a,23730a
   Entered STN: 14 Aug 1997
ΤI
    Polymeric dispersants, pigment dispersions and offset printing ink
    compositions
    Iwase, Koji; Kinoshita, Hideki; Sato, Teruhisa; Ishikawa, Hiroyuki
ΙN
PA
    Sakata Inx Corporation, Japan
SO
   Eur. Pat. Appl., 32 pp.
    CODEN: EPXXDW
DT
    Patent
   English
LA
    ICM C09D017-00
IC
    ICS C09D011-02
    42-12 (Coatings, Inks, and Related Products)
CC
    Section cross-reference(s): 37
FAN.CNT 2
    PATENT NO.
                     KIND DATE
                                       APPLICATION NO.
                                                            DATE
    -----
                             _____
                      ____
                                        _____
                     A2
A3
                            19970702 EP 1996-120596
    EP 781820
PΙ
                                                             19961220
    EP 781820
                             19980107
                       В1
    EP 781820
                             19990908
        R: DE, ES, FR, GB
                            19971125
                                      JP 1996-243843
    JP 09302259 A
                                                             19960913
                           20030414
                      B2 20030414
T3 19991101 ES 1996-120596
    JP 3396585
    ES 2135838
                                                             19961220
                            19970626 CA 1996-2193763
    CA 2193763
                      A1
                                                             19961223
                            20041123
    CA 2193763
                      С
PRAI JP 1995-337383 A
JP 1996-54944 A
                            19951225
                            19960312
                      A
    JP 1996-243843
                            19960913
                       A
CLASS
PATENT NO.
             CLASS PATENT FAMILY CLASSIFICATION CODES
 ______
EP 781820
               ICM C09D017-00
               ICS
                     C09D011-02
               IPCI C09D0017-00 [ICM, 6]; C09D0011-02 [ICS, 6]
               IPCR
                    B01F0017-52 [I,C*]; B01F0017-52 [I,A]; B01F0017-00
                      [I,C*]; B01F0017-00 [I,A]; C09B0067-00 [I,C*];
                      C09B0067-46 [I,A]; C09C0003-10 [I,C*]; C09C0003-10
                      [I,A]; C09D0011-00 [I,C*]; C09D0011-00 [I,A];
                      C09D0011-02 [I,C*]; C09D0011-02 [I,A]; C09D0011-10
                      [I,C*]; C09D0011-10 [I,A]; C09D0017-00 [I,C*];
                      C09D0017-00 [I,A]; C09D0161-00 [I,C*]; C09D0161-04
                      [I,A]; C09D0161-14 [I,A]
                      B01F017/00K; C09B067/00P10B8; C09D011/02B; C09D017/00
               ECLA
                      C09C0003-10 [ICM,6]; C09C0003-10 [ICS,6]; B01F0017-52
 JP 09302259
               IPCI
                      [ICS, 6]; C09D0011-00 [ICS, 6]; C09D0011-02 [ICS, 6];
                      C09D0161-14 [ICS,6]; C09D0161-00 [ICS,6,C*]
               IPCR
                      B01F0017-52 [I,C*]; B01F0017-52 [I,A]; B01F0017-00
                      [I,C*]; B01F0017-00 [I,A]; C09B0067-00 [I,C*];
                      C09B0067-46 [I,A]; C09C0003-10 [I,C*]; C09C0003-10
                      [I,A]; C09D0011-00 [I,C*]; C09D0011-00 [I,A];
                      C09D0011-02 [I,C*]; C09D0011-02 [I,A]; C09D0011-10
                      [I,C*]; C09D0011-10 [I,A]; C09D0017-00 [I,C*];
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C09D0017-00 [I,A]; C09D0161-00 [I,C*]; C09D0161-04
                        [I,A]; C09D0161-14 [I,A]
                 ECLA
                        B01F017/00K; C09B067/00P10B8; C09D011/02B; C09D017/00
 ES 2135838
                 IPCI
                        C09D0017-00 [ICM, 6]; C09D0011-02 [ICS, 6]
                 IPCR
                        B01F0017-52 [I,C*]; B01F0017-52 [I,A]; B01F0017-00
                        [I,C*]; B01F0017-00 [I,A]; C09B0067-00 [I,C*];
                        C09B0067-46 [I,A]; C09C0003-10 [I,C*]; C09C0003-10
                        [I,A]; C09D0011-00 [I,C*]; C09D0011-00 [I,A];
                        C09D0011-02 [I,C*]; C09D0011-02 [I,A]; C09D0011-10
                        [I,C*]; C09D0011-10 [I,A]; C09D0017-00 [I,C*];
                        C09D0017-00 [I,A]; C09D0161-00 [I,C*]; C09D0161-04
                        [I,A]; C09D0161-14 [I,A]
                 ECLA
                        B01F017/00K; C09B067/00P10B8; C09D011/02B; C09D017/00
CA 2193763
                 IPCI
                        C09D0017-00 [ICM,6]; C09D0011-02 [ICS,6]; C09D0007-02
                        [ICS, 6]
                 IPCR
                        B01F0017-52 [I,C*]; B01F0017-52 [I,A]; B01F0017-00
                        [I,C*]; B01F0017-00 [I,A]; C09B0067-00 [I,C*];
                        C09B0067-46 [I,A]; C09C0003-10 [I,C*]; C09C0003-10
                        [I,A]; C09D0011-00 [I,C*]; C09D0011-00 [I,A];
                        C09D0011-02 [I,C*]; C09D0011-02 [I,A]; C09D0011-10
                        [I,C*]; C09D0011-10 [I,A]; C09D0017-00 [I,C*];
                        C09D0017-00 [I,A]; C09D0161-00 [I,C*]; C09D0161-04
                        [I,A]; C09D0161-14 [I,A]
                        B01F017/00K; C09B067/00P10B8; C09D011/02B; C09D017/00
                 ECLA
AΒ
     A pigment dispersion is claimed comprising a pigment, a pigment
     dispersant, and, optionally, a binder resin. The pigment dispersion
     comprises, as pigment dispersant(s), \geq 0.2 parts of a modified
     novolak resin (A) and/or a graft copolymer (B) relative to 100 parts of
     the pigment, (A) and (B) each having an aromatic ring and a ring
structure
     given by ring opening of an epoxy group by a carboxyl group of a
     hydroxycarboxylic acid or their derivative Ink compns. for offset
printing
     containing the pigment dispersion are also disclosed. A typical title
composition
     was prepared by mixing and milling polyethylene wax and rosin-modified
     phenolic resin (Tespol 1355) varnish in a mixture of linseed oil and a
     solvent (Solvent Number 5) with an ink base containing Cu phthalocyanine
pigment,
     reaction product of poly(12-hydroxystearic acid) with glycidyl
     methacrylate-styrene copolymer (preparation given) as pigment dispersant,
     Tespol 1355, linseed oil and Solvent Number 5.
ST
     offset printing ink compn pigment dispersant; pigment dispersant modified
     novolak resin prepn; hydroxystearic acid polymer deriv prepn dispersant;
     polyhydroxystearate glycidyl methacrylate ester macromer dispersant;
     styrene glycidyl methacrylate copolymer pigment dispersant
ΙΤ
    Polyesters, uses
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (aliphatic, reaction products, with glycidyl Ph ether and phenol and
        formalin, dispersants; polymeric dispersants, pigment dispersions and
        offset printing ink compns.)
ΙT
     Phenolic resins, uses
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
```

use); PREP (Preparation); USES (Uses)

```
(epoxy, reaction products, with poly(12-hydroxystearic acid),
        stearates, dispersants; polymeric dispersants, pigment dispersions and
        offset printing ink compns.)
ΙT
        (lithog.; pigment dispersion and offset printing ink composition
containing
       modified novolak resins or polyesters as pigment dispersing agents)
    Phenolic resins, uses
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (modified with 12-hydroxystearic acid-glycidyl Ph ether reaction
        products, dispersants; polymeric dispersants, pigment dispersions and
        offset printing ink compns.)
ΙT
     Phenolic resins, uses
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (novolak, reaction products, with 12-hydroxystearic acid-glycidyl Ph
        ether condensate, dispersants; polymeric dispersants, pigment
        dispersions and offset printing ink compns.)
ΙT
    Epoxy resins, uses
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (phenolic, reaction products, with poly(12-hydroxystearic acid),
        stearates, dispersants; polymeric dispersants, pigment dispersions and
        offset printing ink compns.)
ΙT
     Dispersing agents
    Pigments, nonbiological
        (pigment dispersion and offset printing ink composition containing
modified
       novolak resins or polyesters as pigment dispersing agents)
ΙT
     Linseed oil
     RL: TEM (Technical or engineered material use); USES (Uses)
        (pigment dispersion and offset printing ink composition containing
modified
        novolak resins or polyesters as pigment dispersing agents)
IT
     192709-74-3P, 12-Hydroxystearic acid-Styrene copolymer
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (dispersant; polymeric dispersants, pigment dispersions and offset
        printing ink compns.)
     57-11-4DP, Octadecanoic acid, esters with Epikote 154 and
ΤT
     poly(hydroxystearic acid), uses 64-19-7DP, Acetic acid, esters with
     Epikote 154 and poly(hydroxystearic acid), uses
                                                       101-90-6DP, Resorcinol
     diglycidyl ether, reaction products with phenol novolak resin
     106-14-9DP, 12-Hydroxystearic acid, reaction products with glycidyl Ph
     ether and phenol novolak resin 110-15-6DP, Butanedioic acid, esters
with
     Epikote 154 and poly(hydroxystearic acid), uses
                                                       122-60-1DP, reaction
     products with 12-hydroxystearic acid and phenol novolak resin
     124-30-1DP, 1-Octadecanamine, amides with Epikote 154 and
     poly(hydroxystearic acid)
                                4223-14-7DP, reaction products with modified
                           9003-35-4DP, modified with 12-hydroxystearic
     phenol novolak resin
     acid-glycidyl Ph ether reaction products 15895-57-5DP, reaction
products
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with phenol novolak resin
                               25167-42-4DP, Glycidyl methacrylate-Styrene
     copolymer, reaction products with poly(hydroxystearic acid)
     27924-99-8DP, 12-Hydroxystearic acid polymer, reaction products with
     glycidyl Ph ether and phenol novolak resin 27941-02-2DP,
     12-Hydroxystearic acid polymer, sru, reaction products with
epoxy-containing
               29564-58-7DP, Glycidyl methacrylate-Methyl
    polymers
methacrylate-Styrene
     copolymer, reaction products with poly(hydroxystearic acid)
     52300-37-5DP, reaction products with modified phenol novolak resin
     63939-13-9DP, Epikote 154, reaction products with poly(hydroxystearic
     acid), stearates 66251-30-7DP, Glycidyl methacrylate-Vinyltoluene
     copolymer, reaction products with poly(hydroxystearic acid)
     67076-27-1DP, p-Chlorostyrene-Glycidyl methacrylate copolymer, reaction
    products with poly(hydroxystearic acid) 86249-19-6DP, Benzyl
    methacrylate-Glycidyl methacrylate copolymer, reaction products with
    poly(hydroxystearic acid)
                               94290-63-8DP, 2,3-Epoxy-2-methylpropyl
    methacrylate-Styrene copolymer, reaction products with
poly(hydroxystearic
            192709-72-1DP, Dimethylstyrene-Glycidyl methacrylate copolymer,
     acid)
     reaction products with poly(hydroxystearic acid) 192709-73-2P,
     12-Hydroxystearic acid polymer glycidyl methacrylate ester-Styrene graft
     copolymer
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (dispersants; polymeric dispersants, pigment dispersions and offset
        printing ink compns.)
ΙT
     147-14-8P, Copper phthalocyanine
     RL: IMF (Industrial manufacture); TEM (Technical or engineered material
     use); PREP (Preparation); USES (Uses)
        (pigment; polymeric dispersants, pigment dispersions and offset
        printing ink compns.)
ΤT
     192828-15-2, Tespol 1355
     RL: TEM (Technical or engineered material use); USES (Uses)
        (varnish; polymeric dispersants, pigment dispersions and offset
       printing ink compns.)
OSC.G
              THERE ARE 4 CAPLUS RECORDS THAT CITE THIS RECORD (4 CITINGS)
UPOS.G Date last citing reference entered STN: 16 Feb 2009
      CAPLUS 2006:564323; 2002:978263; 2002:946378; 1999:726113
L4
    ANSWER 15 OF 15 CAPLUS COPYRIGHT 2009 ACS on STN
     1987:41630 CAPLUS
ΑN
    106:41630
DN
OREF 106:6805a,6808a
     Entered STN: 07 Feb 1987
ED
ΤI
     Radiation-sensitive negative-working resists
     Obara, Hidekatsu; Shimizu, Akihiro; Yokota, Akira; Nakane, Hisashi
ΙN
PA
     Tokyo Ohka Kogyo Co., Ltd., Japan
     Jpn. Kokai Tokkyo Koho, 5 pp.
SO
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
IC
     ICM G03C001-71
     ICS G03C005-08; G03F007-10
CC
     74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other
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Reprographic Processes)

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	PATENT NO.		KIND	DATE	APPLICATION NO.	DATE
	JP 61148445 JP 06044153 JP 1984-270		 А В	19860707 19940608 19841224	JP 1984-270753	19841224
	-	CLASS	PATENT	FAMILY CLASS	IFICATION CODES	
JP 61148445		ICS IPCI IPCR	G03C000 [ICS,4] G03C000 [I,C*]; G03F000 [I,A]	-08; G03F007 1-71 [ICM, 4] 5-08 [I,C*]; G03F0007-03 7-20 [I,A];	-10 ; G03C0005-08 [ICS,4]; G03C0005-08 [I,A]; G03 8 [I,A]; G03F0007-20 [I H01L0021-02 [I,C*]; H01	F0007-038
		ECLA	G03F007	/038		

AB The resists having firm bonding to substrates and especially high resistance to

dry etching are composed of a polymer or a copolymer having repeating units -H2CCRR1- (R = H, Me; R1 = OCOR2, COOR2, COOCH2R2; R2 = haloalkyl-substituted Ph). Thus, poly(vinyl benzoate) was prepared by polymerization of 100 g vinyl benzoate with AIBN. The obtained polymer

chloromethylated using chloromethyl ether and AlCl3. The obtained polymer $\,$

contained 58 mol% chloromethyl group and its solution (of 10 g) was applied $\,$

on a pattern-etched Si substrate deposited with a $0.5-\mu$ Al layer and then dried to obtain a $1-\mu$ layer. Exposure to UV through a quartz pattern mask and development in a Me Cellosolve-isoamyl acetate mixture followed by rinsing with iso-PrOH gave a $0.5-\mu$ line pattern, which was postbaked at 140°. Dry etching in a CCl4-He mixture rapidly etched the Al layer but did not affect the resist layer. Reetching in O2

the resist layer to obtain a 0.5- $\!\mu$ Al pattern with steps on the surface.

- ST neg photoresist dry etching resistant; halomethylated polymer photoresist etching resistant; lithog neg photoresist etch resistant
- IT Resists

was

(photo-, neg.-working, dry etching-resistant, halomethylated polymers as)

IT 24991-32-0D, Poly(vinyl benzoate), chloromethylated 26838-25-5D, Benzyl methacrylate-methyl methacrylate copolymer, chloromethylated 86249-19-6D, chloromethylated 106143-11-7D, bromoethylated RL: USES (Uses)

(lithog. photoresist, neg.-working, dry etching-resistant)

=> d his

(FILE 'HOME' ENTERED AT 16:42:14 ON 01 DEC 2009)

FILE 'CAPLUS' ENTERED AT 16:42:28 ON 01 DEC 2009

L1 1 S JP58048048/PN

FILE 'REGISTRY' ENTERED AT 16:43:24 ON 01 DEC 2009

L2 1 S 86249-19-6/RN

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SET NOTICE LOGIN DISPLAY

FILE 'CAPLUS' ENTERED AT 16:43:41 ON 01 DEC 2009

L3 16 S L2

L4 15 S L3 NOT L1

=> log y

COST IN U.S. DOLLARS

SINCE FILE
ENTRY
SESSION
FULL ESTIMATED COST

SINCE FILE
TOTAL
60.57

DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)

SINCE FILE
ENTRY
SESSION
CA SUBSCRIBER PRICE

-12.30
-13.12

STN INTERNATIONAL LOGOFF AT 16:44:25 ON 01 DEC 2009